BQ2407x 具有电源路径的独立型单芯 1.5A 线性电池充电器

1 特性

- 完全符合 USB 充电器标准
  - 最大输入电流可选 100mA 和 500mA
  - 100mA 最大电流限制可确保充电符合 USB-IF 标准
  - 基于输入的动态电源管理 (V_{IN}-DPM)，用于保护免受不良 USB 电源损害
- 提供功能安全型 (BQ24074)
  - 可帮助进行功能安全系统设计的文档
- 28V 输入额定值，具有过压保护功能
- 集成动态电源路径管理 (DPPM) 功能可同时独立进行系统供电和对电池充电
- 借助电流监控输出 (ISET) 功能可支持高达 1.5A 的充电电流
- 针对墙上适配器的高达 1.5A 的可编程输入电流限制
- 系统输出跟踪电池电压 (BQ24072)
- 可编程终止电流 (BQ24074)
- 通过 SYSOFF 输入实现电池断开功能（BQ24075、BQ24079）
- 可编程预充电和快速充电安全计时器
- 反向电流、短路和热保护
- NTC 热敏电阻输入
- 专有启动序列可限制浪涌电流
- 具有充电中/充电完成和电源正常的状态指示
- 安全相关认证：
  - IEC 62368-1 认证 (BQ24072)

2 应用

- TWS 充电盒和耳机
- 游戏附件
- 可视门铃、IP 网络摄像头
- 资产跟踪和机群管理
- 便携式医疗设备

3 说明

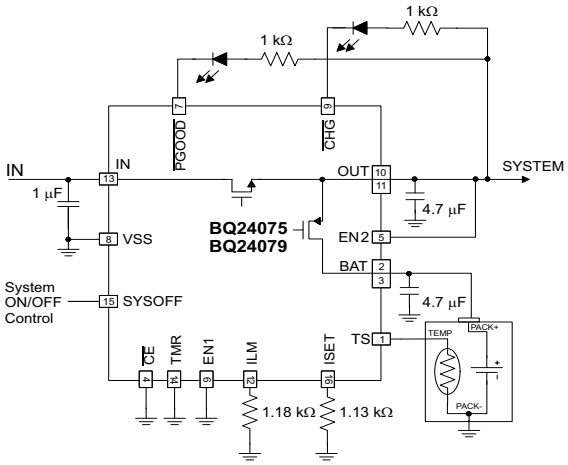
BQ2407x 系列器件是集成型锂离子线性充电器和系统电源路径管理器件，适用于空间受限的便携式应用。这类器件通过 USB 端口或交流适配器运行，最高支持 1.5A 的充电电流。它们在输入电压范围内具有输入电压保护功能，因此支持非稳压适配器。BQ2407x 的 USB 输入电流限制精度和启动序列使得这款器件能够符合 USB-IF 浪涌电流规范。此外，输入动态电源管理 (V_{IN}-DPM) 可防止充电器损毁错误配置的 USB 电源。

BQ2407x 具有动态电源路径管理 (DPPM)，此功能可在为系统供电的同时独立地为电池充电。当输入电流限制引起系统输出降至 DPPM 阈值时，DPPM 电路将减少充电电流；因此，可在为系统负载供电时随时监测充电电流。这个特性减少了电池上充放电周期的数量，可实现充电正常终止并使得系统能够在由有缺陷或者不完整的电池组供电的情况下运行。

器件信息

器件型号(1)	封装	封装尺寸（标称值）
BQ24072	VQFN (16)	3.00mm × 3.00mm
BQ24073		
BQ24074		
BQ24075		
BQ24079		

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。



典型应用电路

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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision M (August 2019) to Revision N (October 2021) — **Page**

- 向“特性”添加了“提供功能安全型 (BQ24074)” 1
- 向“特性”添加了“安全相关认证：IEC 62368-1 认证 (BQ24072)” 1
- 更改了应用 1
- Changed BQ24079T information and package in 节 6 6
- Added $I_{BAT(PDWN)}$ TYP value 12
- Added I_{IN} TYP values 12
- Added I_{CC} TYP value 12

Changes from Revision L (June 2018) to Revision M (August 2019) — **Page**

- 更改了文档标题 1
- Changed the Device Comparison Table 6
- Deleted the *Dissipation Ratings* table 11
- Changed V_{IN-LOW} To V_{IN-DPM} in the *Functional Block Diagram* 18
- Changed text From: "the DPPM loop or the $V_{IN-(LOW)}$ loop." To: "the DPPM loop or the V_{IN-DPM} loop." in the *Battery Charging* secton 24
- Chganged text From: " input voltage has fallen to $V_{IN(LOW)}$" To: "input voltage has fallen to V_{IN-DPM}" in the *Dynamic Charge Timers (TMR Input)* scrtion 27
- Changed 方程式 11 42

Changes from Revision K (March 2015) to Revision L (June 2018) — **Page**

- Deleted MARKINGS from the Device Comparison Table 6
- Added the RGT0016B and RGT0016C package information to the Device Comparison Table 6
- Changed the Pinout images and descriptions 7
- Change description of the $\overline{CE}$ pin From: "Connect $\overline{CE}$ to a high logic level to place the battery charger in standby mode. In standby mode,..." To ""Connect $\overline{CE}$ to a high logic level to disable battery charging. OUT is active and battery supplement mode is still available." 7

- "Changed text in the third paragraph of the *Power On* section From: When V_{OUT} is above V_{SC},..." To: "When V_{OUT} is above $V_{O(SC1)}$,..." 19
- Changed text From: "The valid resistor range is 590 Ω to 5.9 kΩ." To: "The valid resistor range is 590 Ω to 8.9 kΩ." in the *Battery Charging* section 24
- Changed From: $V_{IN(DT)}$ To: V_{BAT} + $V_{IN(DT)}$ in 表 9-1 28
- Changed I_{NTC} To: I_{TS} in 图 9-9 29

Changes from Revision J (January 2015) to Revision K (March 2015) **Page**

- Deleted package type code from Device Comparison Table. See the POA at the end of the data sheet. 6
- Changed I_{CHG} Battery fast charge current range MIN specification from "150 mA" to "100 mA" 12

Changes from Revision I (January 2014) to Revision J (January 2015) **Page**

- 添加了 *ESD 等级* 表、*特性说明* 部分、*器件功能模式*、*应用和实施* 部分、*电源相关建议* 部分、*布局* 部分、*器件和文档支持* 部分以及*机械、封装和可订购信息* 部分 1

Changes from Revision H (December 2013) to Revision I (January 2014) **Page**

- Changed resistor value from "3 kΩ" to "8.9 kΩ" in the Pin Functions table ISET Description paragraph 7
- Changed R_{ISET} spec MAX value from "3000" to "8900" in the Recommended Operating Conditions table 10
- Changed resistor value from "3 kΩ" to "5.9 kΩ" in the *Battery Charging* section paragraph 24

Changes from Revision G (July 2011) to Revision H (December 2013) **Page**

- Changed I_{CHG} Battery fast charge current range MIN specification from "300 mA" to "150 mA" 12

Changes from Revision F (September 2010) to Revision G (July 2011) **Page**

- Added ESD human body model specification to Abs Maximum Ratings table 10

Changes from Revision E (August 2010) to Revision F (September 2010) **Page**

- Changed 10 x 45 s/kΩ to 10 x 48 s/kΩ under section Program 6.25hour.....(TMR) 34

Changes from Revision D (June 2009) to Revision E (August 2010) **Page**

- Changed globally RT1 and RT2 to Rs and Rp 29
- Added equations 2 and 3 plus explanations and table 29

Changes from Revision C (March 2009) to Revision D (June 2009) **Page**

- 添加了器件型号 BQ24079 1

Changes from Revision B (January 2009) to Revision C (March 2009) **Page**

- Changed Maximum input current factor values. 12

Changes from Revision A (December 2008) to Revision B (January 2009) **Page**

- Changed $V_{BAT(REG)}$ max value From 4.24 V To: 4.23 V 12

Changes from Revision * (September 2008) to Revision A (December 2008) **Page**

- 更改了器件特性....1
- 更改了说明....1
- 更改了典型应用电路....1
- Changed description of $\overline{CHG}$ pin....7
- Changed SYSOFF Description....7
- Added 图 10-5 through 图 8-1....14
- Changed DETAILED FUNCTIONAL DESCRIPTION section....17
- Changed the *Functional Block Diagram* 18
- Changed text in section - STATUS INDICATORS ($\overline{PGOOD}$, $\overline{CHG}$)....28
- Changed Table - $\overline{CHG}$ STATUS INDICATOR....28
- Changed 方程式 8 and 方程式 9 29
- Changed APPLICATION CIRCUITS section....33
- Added Using BQ24075 to Disconnect the Battery from the System, 图 10-13....38
- Changed section - Half-Wave Adaptors....39

5 说明（续）

此外，该系列充电器可提供经稳压的系统输入，即使在电池完全放电的情况下，也可使系统在连接电源后实现瞬间开启。当适配器无法提供峰值系统电流时，电源路径管理架构还允许使用电池来满足系统电流要求，因此可使用更小的适配器。

电池充电过程分为三个阶段：预充电、恒流充电和恒压充电。在所有的充电阶段，一个内部控制环路监测 IC 结温并且如果超过此内部温度阈值则减少充电电流。充电器功率级和充电电流感应功能完全集成在了一起。该充电器具高精度电流和电压调节环路、充电状态显示和充电终止功能。输入电流限制和充电电流可使用外部电阻器进行编程。

6 Device Comparison Table

PART NUMBER (1) (2)	V_{OVP}	$V_{BAT(REG)}$	$V_{OUT(REG)}$	V_{DPPM}	TS METHOD	OPTIONAL FUNCTION	PACKAGE
BQ24072	6.6 V	4.2 V	V_{BAT} + 225 mV	$V_{O(REG)}$ – 100 mV	Current Based	TD	RGT0016C
BQ24073	6.6 V	4.2 V	4.4 V	$V_{O(REG)}$ – 100 mV		TD	
BQ24074	10.5 V	4.2 V	4.4 V	$V_{O(REG)}$ – 100 mV		ITERM	
BQ24075	6.6 V	4.2 V	5.5 V	4.3 V		SYSOFF	
BQ24076	6.6 V	4.4 V	V_{BAT} + 225 mV	$V_{O(REG)}$ – 100 mV		SYSOFF	
BQ24078	6.6 V	4.35 V	V_{BAT} + 225 mV	$V_{O(REG)}$ – 100 mV		SYSOFF	
BQ24079	6.6 V	4.1 V	5.5 V	4.3 V		SYSOFF	
BQ24072T	6.6 V	4.2 V	V_{BAT} + 225 mV	$V_{O(REG)}$ – 100 mV	Voltage Based	TD	
BQ24075T	6.6 V	4.2 V	5.5 V	4.3 V		SYSOFF	
BQ24079T	6.6 V	4.1 V	5.5 V	4.3 V		SYSOFF	

(1) For all available packages, see the orderable addendum at the end of the data sheet
(2) This product is RoHS compatible, including a lead concentration that does not exceed 0.1% of total product weight, and is suitable for use in specified lead-free soldering processes. In addition, this product uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

7 Pin Configuration and Functions

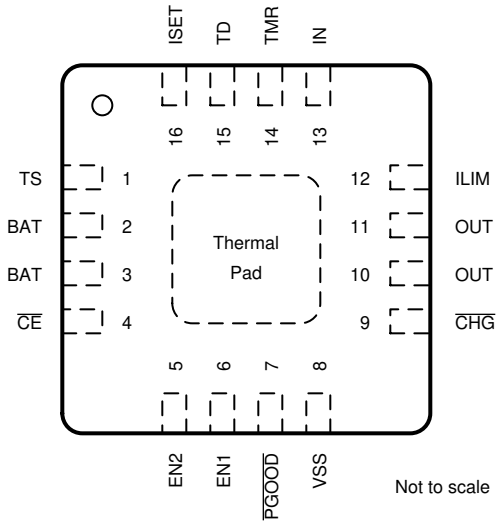


图 7-1. BQ24072, BQ24073 RGT0016B Package 16 Pins Top View

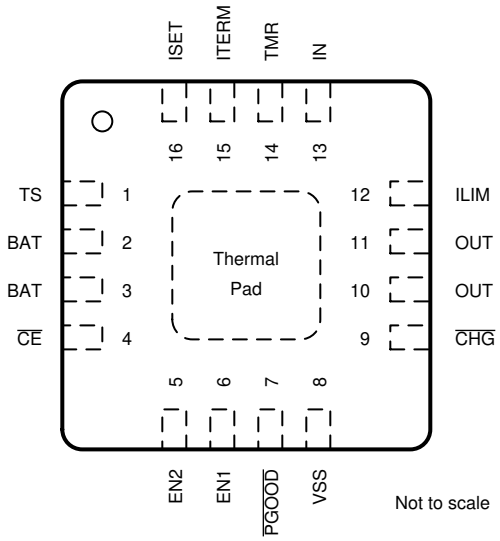


图 7-2. BQ24074 RGT0016B Package 16 Pins Top View

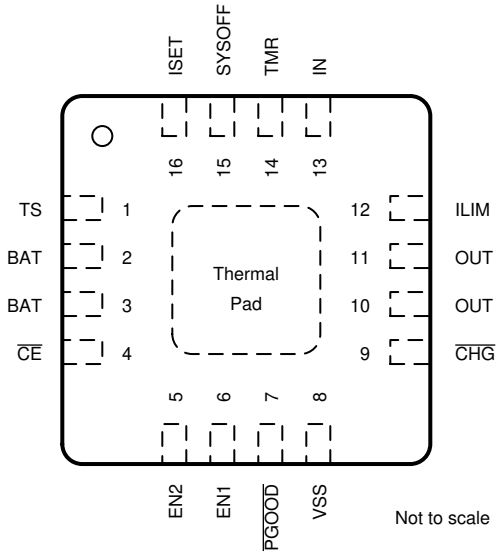


图 7-3. BQ24075 RGT0016C Package, BQ24079 RGT0016B Package 16 Pins Top View

表 7-1. Pin Functions

PIN				I/O	DESCRIPTION
NAME	'72, '73	'74	'75, '79		
BAT	2, 3	2, 3	2, 3	I/O	Charger Power Stage Output and Battery Voltage Sense Input. Connect BAT to the positive terminal of the battery. Bypass BAT to VSS with a 4.7-μF to 47-μF ceramic capacitor.
CE	4	4	4	I	Charge Enable Active-Low Input. Connect CE to a high logic level to disable battery charging. OUT is active and battery supplement mode is still available. Connect CE to a low logic level to enable the battery charger. CE is internally pulled down with approximately 285 kΩ. Do not leave CE unconnected to ensure proper operation.
CHG	9	9	9	O	Open-Drain Charging Status Indication Output. CHG pulls to VSS when the battery is charging. CHG is high impedance when charging is complete and when charger is disabled. Connect CHG to the desired logic voltage rail using a 1kΩ-100kΩ resistor, or use with an LED for visual indication.
EN1	6	6	6	I	Input Current Limit Configuration Inputs. Use EN1 and EN2 control the maximum input current and enable USB compliance. See 表 7-2 for the description of the operation states. EN1 and EN2 are internally pulled down with ≠285 kΩ. Do not leave EN1 or EN2 unconnected to ensure proper operation.
EN2	5	5	5	I	
ILIM	12	12	12	I	Adjustable Current Limit Programming Input. Connect a 1100-Ω to 8-kΩ resistor from ILIM to VSS to program the maximum input current (EN2=1, EN1=0). The input current includes the system load and the battery charge current. Leaving ILIM unconnected disables all charging.
IN	13	13	13	I	Input Power Connection. Connect IN to the external DC supply (AC adapter or USB port). The input operating range is 4.35 V to 6.6 V (BQ24072, BQ24073, BQ24075, and BQ24079) or 4.35 V to 10.5 V (bq24074). The input can accept voltages up to 26 V without damage but operation is suspended. Connect bypass capacitor 1 μF to 10 μF to VSS.
ISET	16	16	16	I/O	Fast Charge Current Programming Input. Connect a 590-Ω to 8.9-kΩ resistor from ISET to VSS to program the fast charge current level. Charging is disabled if ISET is left unconnected. While charging, the voltage at ISET reflects the actual charging current and can be used to monitor charge current. See 节 9.3.5.1 for more details.
ITERM	–	15	–	I	Termination Current Programming Input. Connect a 0-Ω to 15-kΩ resistor from ITERM to VSS to program the termination current. Leave ITERM unconnected to set the termination current to the default 10% termination threshold.
OUT	10, 11	10, 11	10, 11	O	System Supply Output. OUT provides a regulated output when the input is below the OVP threshold and above the regulation voltage. When the input is out of the operation range, OUT is connected to V_{BAT} except when SYSOFF is high (BQ24075 and BQ24079 only). Connect OUT to the system load. Bypass OUT to VSS with a 4.7-μF to 47-μF ceramic capacitor.
PGOOD	7	7	7	O	Open-drain Power Good Status Indication Output. PGOOD pulls to VSS when a valid input source is detected. PGOOD is high-impedance when the input power is not within specified limits. Connect PGOOD to the desired logic voltage rail using a 1-kΩ to 100-kΩ resistor, or use with an LED for visual indication.
SYSOFF	–	–	15	I	System Enable Input. Connect SYSOFF high to turn off the FET connecting the battery to the system output. When an adapter is connected, charging is also disabled. Connect SYSOFF low for normal operation. SYSOFF is internally pulled up to V_{BAT} through a large resistor (approximately 5 MΩ). Do not leave SYSOFF unconnected to ensure proper operation.

表 7-1. Pin Functions (continued)

PIN				I/O	DESCRIPTION
NAME	'72, '73	'74	'75, '79		
TD	15	–	–	I	Termination Disable Input. Connect TD high to disable charger termination. Connect TD to VSS to enable charger termination. TD is checked during startup only and cannot be changed during operation. See the TD section in this datasheet for a description of the behavior when termination is disabled. TD is internally pulled down to VSS with approximately 285 kΩ. Do not leave TD unconnected to ensure proper operation.
Thermal Pad	—	—	—	–	There is an internal electrical connection between the exposed thermal pad and the VSS pin of the device. The thermal pad must be connected to the same potential as the VSS pin on the printed circuit board. Do not use the thermal pad as the primary ground input for the device. VSS pin must be connected to ground at all times.
TMR	14	14	14	I	Timer Programming Input. TMR controls the pre-charge and fast-charge safety timers. Connect TMR to VSS to disable all safety timers. Connect a 18-kΩ to 72-kΩ resistor between TMR and VSS to program the timers a desired length. Leave TMR unconnected to set the timers to the default values.
TS	1	1	1	I	External NTC Thermistor Input. Connect the TS input to the NTC thermistor in the battery pack. TS monitors a 10kΩ NTC thermistor. For applications that do not use the TS function, connect a 10-kΩ fixed resistor from TS to VSS to maintain a valid voltage level on TS.
VSS	8	8	8	–	Ground. Connect to the thermal pad and to the ground rail of the circuit.

表 7-2. EN1/EN2 Settings

EN2	EN1	MAXIMUM INPUT CURRENT INTO IN PIN
0	0	100 mA. USB100 mode
0	1	500 mA. USB500 mode
1	0	Set by an external resistor from ILIM to VSS
1	1	Standby (USB suspend mode)

8 Specifications

8.1 Absolute Maximum Ratings(1)

over the 0°C to 125°C operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_I	Input Voltage	IN (with respect to VSS)	–0.3	28	V
		BAT (with respect to VSS)	–0.3	5	V
		OUT, EN1, EN2, $\overline{CE}$, TS, ISET, $\overline{PGOOD}$, $\overline{CHG}$, ILIM, TMR, ITERM, SYSOFF, TD (with respect to VSS)	–0.3	7	V
I_I	Input Current	IN		1.6	A
I_O	Output Current (Continuous)	OUT		5	A
		BAT (Discharge mode)		5	A
		BAT (Charging mode)		1.5(2)	A
	Output Sink Current	$\overline{CHG}$, $\overline{PGOOD}$		15	mA
T_J	Junction temperature		–40	150	°C
T_{stg}	Storage temperature		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under 节 8.3 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. All voltage values are with respect to the network ground terminal unless otherwise noted.

(2) The IC operational charging life is reduced to 20,000 hours, when charging at 1.5A and 125°C. The thermal regulation feature reduces charge current if the IC’ s junction temperature reaches 125°C; thus without a good thermal design the maximum programmed charge current may not be reached.

8.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

8.3 Recommended Operating Conditions

			MIN	MAX	UNIT
V_I	IN voltage range		4.35	26	V
	IN operating voltage range	’ 72, ’ 73, ‘75, '79	4.35	6.4	V
		‘74	4.35	10.2	
I_{IN}	Input current, IN pin			1.5	A
I_{OUT}	Current, OUT pin			4.5	A
I_{BAT}	Current, BAT pin (Discharging)			4.5	A
I_{CHG}	Current, BAT pin (Charging)			1.5(2)	A
T_J	Junction Temperature		–40	125	°C
R_{ILIM}	Maximum input current programming resistor		1100	8000	Ω
R_{ISET}	Fast-charge current programming resistor (1)		590	8900	Ω
R_{ITERM}	Termination current programming resistor		0	15	kΩ
R_{TMR}	Timer programming resistor		18	72	kΩ

(1) Use a 1% tolerance resistor for R_{ISET} to avoid issues with the R_{ISET} short test when using the maximum charge current setting.

(2) The IC operational charging life is reduced to 20,000 hours, when charging at 1.5A and 125°C. The thermal regulation feature reduces charge current if the IC’ s junction temperature reaches 125°C; thus without a good thermal design the maximum programmed charge current may not be reached.

8.4 Thermal Information

THERMAL METRIC(1)		BQ2407x RGT 16 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	44.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	54.2	
$R_{\theta JB}$	Junction-to-board thermal resistance	17.2	
ψ_{JT}	Junction-to-top characterization parameter	1.0	
ψ_{JB}	Junction-to-board characterization parameter	17.1	
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	3.8	

(1) For more information about traditional and new thermal metrics, see the *Semiconductor IC Package Thermal Metrics* application report.

8.5 Electrical Characteristics

Over junction temperature range (0° ≤ T_J ≤ 125°C) and the recommended supply voltage range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
INPUT							
UVLO	Undervoltage lock-out	V_{IN}: 0 V → 4 V		3.2	3.3	3.4	V
V_{hys}	Hysteresis on UVLO	V_{IN}: 4 V → 0 V		200		300	mV
$V_{IN(DT)}$	Input power detection threshold	Input power detected when V_{IN} > V_{BAT} + $V_{IN(DT)}$ V_{BAT} = 3.6 V, VIN: 3.5 V → 4 V		55	80	130	mV
V_{hys}	Hysteresis on $V_{IN(DT)}$	V_{BAT} = 3.6 V, V_{IN}: 4 V → 3.5 V		20			mV
$t_{DGL(PGOOD)}$	Deglitch time, input power detected status	Time measured from V_{IN}: 0 V → 5 V 1 μs rise-time to $\overline{PGOOD}$ = LO			1.2		ms
V_{OVP}	Input overvoltage protection threshold	V_{IN}: 5 V → 7 V	(’ 72, ’ 73, ’ 75, '79)	6.4	6.6	6.8	V
		V_{IN}: 5 V → 11 V	(’ 74)	10.2	10.5	10.8	
V_{hys}	Hysteresis on OVP	V_{IN}: 7 V → 5V	(’ 72, ’ 73, ’ 75, '79)		110		mV
		V_{IN}: 11 V → 5 V	(’ 74)		175		
$t_{DGL(OVP)}$	Input overvoltage blanking time (OVP fault deglitch)				50		μs
t_{REC}	Input overvoltage recovery time	Time measured from V_{IN}: 11 V → 5 V with 1 μs fall-time to $\overline{PGOOD}$ = LO			1.2		ms
ILIM, ISET SHORT-CIRCUIT DETECTION (CHECKED DURING STARTUP)							
I_{SC}	Current source	V_{IN} > UVLO and V_{IN} > V_{BAT} + $V_{IN(DT)}$			1.3		mA
V_{SC}		V_{IN} > UVLO and V_{IN} > V_{BAT} + $V_{IN(DT)}$			520		mV
QUIESCENT CURRENT							
$I_{BAT(PDWN)}$	Sleep current into BAT pin	$\overline{CE}$ = LO or HI, input power not detected, No load on OUT pin, T_J = 85°C			4.3	6.5	μA
I_{IN}	Standby current into IN pin	EN1= HI, EN2=HI, V_{IN} = 6 V, T_J= 85°C			41.3	50	μA
		EN1= HI, EN2=HI, V_{IN} = 10 V, T_J= 85°C			99.8	200	
I_{CC}	Active supply current, IN pin	$\overline{CE}$ = LO, V_{IN} = 6 V, no load on OUT pin, V_{BAT} > $V_{BAT(REG)}$, (EN1, EN2) ≠ (HI, HI)			1.1	1.5	mA
POWER PATH							
$V_{DO(IN-OUT)}$	V_{IN} – V_{OUT}	V_{IN} = 4.3 V, I_{IN} = 1 A, V_{BAT} = 4.2 V			300	475	mV
$V_{DO(BAT-OUT)}$	V_{BAT} – V_{OUT}	I_{OUT} = 1 A, V_{IN} = 0 V, V_{BAT} > 3 V			50	100	mV
$V_{O(REG)}$	OUT pin voltage regulation (BQ24072)	V_{IN} > V_{OUT} + $V_{DO(IN-OUT)}$, V_{BAT} < 3.2 V		3.3	3.4	3.5	V
		V_{IN} > V_{OUT} + $V_{DO(IN-OUT)}$, V_{BAT} ≥ 3.2 V		V_{BAT} + 150mV	V_{BAT} + 225mV	V_{BAT} + 270mV	
	OUT pin voltage regulation (BQ24073, BQ24074)	V_{IN} > V_{OUT} + $V_{DO(IN-OUT)}$		4.3	4.4	4.5	
	OUT pin voltage regulation (BQ24075, BQ24079)	V_{IN} > V_{OUT} + $V_{DO(IN-OUT)}$		5.4	5.5	5.6	
I_{IN}max	Maximum input current	EN1 = LO, EN2 = LO		90	95	100	mA
		EN1 = HI, EN2 = LO		450	475	500	
		EN2 = HI, EN1 = LO			K_{ILIM}/R_{ILIM}		A
K_{ILIM}	Maximum input current factor	I_{LIM} = 500 mA to 1.5 A		1500	1610	1720	AΩ
		I_{LIM} = 200 mA to 500 mA		1330	1525	1720	
I_{IN}max	Programmable input current limit range	EN2 = HI, EN1 = LO, R_{ILIM} = 8 kΩ to 1.1 kΩ		200		1500	mA
V_{IN-DPM}	Input voltage threshold when input current is reduced	EN2 = LO, EN1 = X		4.35	4.5	4.63	V
V_{DPPM}	Output voltage threshold when charging current is reduced		(’ 72, ’ 73, ’ 74)	$V_{O(REG)}$ – 180mV	$V_{O(REG)}$ – 100mV	$V_{O(REG)}$ – 30mV	V
			(’ 75, '79)	4.2	4.3	4.4	V
V_{BSUP1}	Enter battery supplement mode	V_{BAT} = 3.6 V, R_{ILIM} = 1.5 kΩ, R_{LOAD} = 10 Ω → 2 Ω			V_{OUT} ≤ V_{BAT} – 40mV		V
V_{BSUP2}	Exit battery supplement mode	V_{BAT} = 3.6 V, R_{ILIM} = 1.5 kΩ, R_{LOAD} = 2 Ω → 10 Ω			V_{OUT} ≥ V_{BAT} – 20mV		V
$V_{O(SC1)}$	Output short-circuit detection threshold, power-on	V_{IN} > V_{UVLO} and V_{IN} > V_{BAT} + $V_{IN(DT)}$		0.8	0.9	1	V
$V_{O(SC2)}$	Output short-circuit detection threshold, supplement mode V_{BAT} – V_{OUT} > $V_{O(SC2)}$ indicates short-circuit	V_{IN} > V_{UVLO} and V_{IN} > V_{BAT} + $V_{IN(DT)}$		200	250	300	mV
$t_{DGL(SC2)}$	Deglitch time, supplement mode short circuit				250		μs
$t_{REC(SC2)}$	Recovery time, supplement mode short circuit				60		ms

8.5 Electrical Characteristics (continued)

Over junction temperature range (0° ≤ T_J ≤ 125°C) and the recommended supply voltage range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
BATTERY CHARGER							
I_{BAT}	Source current for BAT pin short-circuit detection	V_{BAT} = 1.5 V		4	7.5	11	mA
$V_{BAT(SC)}$	BAT pin short-circuit detection threshold	V_{BAT} rising		1.6	1.8	2	V
$V_{BAT(REG)}$	Battery charge voltage		('72, '73, '74, '75)	4.16	4.20	4.23	V
			('79)	4.059	4.100	4.141	
V_{LOWV}	Pre-charge to fast-charge transition threshold	V_{IN} > V_{UVLO} and V_{IN} > V_{BAT} + $V_{IN(DT)}$		2.9	3	3.1	V
$t_{DGL1(LOWV)}$	Deglitch time on pre-charge to fast-charge transition				25		ms
$t_{DGL2(LOWV)}$	Deglitch time on fast-charge to pre-charge transition				25		ms
I_{CHG}	Battery fast charge current range	$V_{BAT(REG)}$ > V_{BAT} > V_{LOWV}, V_{IN} = 5 V $\overline{CE}$ = LO, EN1 = LO, EN2 = HI		100		1500	mA
	Battery fast charge current	$\overline{CE}$ = LO, EN1= LO, EN2 = HI, V_{BAT} > V_{LOWV}, V_{IN} = 5 V, I_{IN}max > I_{CHG}, no load on OUT pin, thermal loop and DPPM loop not active			K_{ISET}/R_{ISET}		A
K_{ISET}	Fast charge current factor			797	890	975	AΩ
I_{PRECHG}	Pre-charge current				K_{PRECHG}/R_{ISET}		A
K_{PRECHG}	Pre-charge current factor			70	88	106	AΩ
I_{TERM}	Termination comparator detection threshold (internally set)	$\overline{CE}$ = LO, (EN1, EN2) ≠ (LO, LO), V_{BAT} > V_{RCH}, t < t_{MAXCH}, V_{IN} = 5 V, DPPM loop and thermal loop not active		0.09×I_{CHG}	0.1×I_{CHG}	0.11×I_{CHG}	A
		$\overline{CE}$ = LO, (EN1, EN2) = (LO, LO), V_{BAT} > V_{RCH}, t < t_{MAXCH}, V_{IN} = 5 V, DPPM loop and thermal loop not active		0.027×I_{CHG}	0.033×I_{CHG}	0.040×I_{CHG}	
$I_{BIAS(ITERM)}$	Current for external termination-setting resistor	V_{IN} > V_{UVLO} and V_{IN} > V_{BAT} + $V_{IN(DT)}$		72	75	78	μA
I_{TERM}	Termination current threshold (externally set) (BQ24074)				K_{ITERM} × R_{ITERM} / R_{ISET}		A
K_{ITERM}	K Factor for termination detection threshold (externally set) (BQ24074)	USB500 or ISET mode(EN1, EN2) ≠ (LO, LO) $\overline{CE}$ = LO, V_{BAT} > V_{RCH}, t < t_{MAXCH}, V_{IN} = 5 V, DPPM loop and thermal loop not active		0.0225	0.0300	0.0375	A
		USB100 mode (EN1, EN2) = (LO, LO), $\overline{CE}$ = LO, V_{BAT} > V_{RCH}, t < t_{MAXCH}, V_{IN} = 5 V, DPPM loop and thermal loop not active		0.008	0.0100	0.012	
$t_{DGL(TERM)}$	Deglitch time, termination detected				25		ms
V_{RCH}	Recharge detection threshold	V_{IN} > V_{UVLO} and V_{IN} > V_{BAT} + $V_{IN(DT)}$		$V_{BAT(REG)}$ – 140mV	$V_{BAT(REG)}$ – 100mV	$V_{BAT(REG)}$ – 60mV	V
$t_{DGL(RCH)}$	Deglitch time, recharge threshold detected				62.5		ms
$t_{DGL(NO-IN)}$	Delay time, input power loss to OUT LDO turn-off	V_{BAT} = 3.6 V. Time measured from V_{IN}: 5 V → 3 V 1 μs fall-time			20		ms
$I_{BAT(DET)}$	Sink current for battery detection	V_{BAT} = 2.5 V		5	7.5	10	mA
t_{DET}	Battery detection timer	BAT high or low			250		ms
BATTERY CHARGING TIMERS							
t_{PRECHG}	Pre-charge safety timer value	TMR = floating		1440	1800	2160	s
t_{MAXCHG}	Charge safety timer value	TMR = floating		14400	18000	21600	s
t_{PRECHG}	Pre-charge safety timer value	18 kΩ < R_{TMR} < 72 kΩ			R_{TMR} × K_{TMR}		s
t_{MAXCHG}	Charge safety timer value	18 kΩ < R_{TMR} < 72 kΩ			10×R_{TMR} ×K_{TMR}		s
K_{TMR}	Timer factor			36	48	60	s/kΩ
BATTERY-PACK NTC MONITOR(1)							
I_{NTC}	NTC bias current	V_{IN} > UVLO and V_{IN} > V_{BAT} + $V_{IN(DT)}$		72	75	78	μA
V_{HOT}	High temperature trip point	Battery charging, V_{TS} Falling		270	300	330	mV
$V_{HYS(HOT)}$	Hysteresis on high trip point	Battery charging, V_{TS} Rising from V_{HOT}			30		mV
V_{COLD}	Low temperature trip point	Battery charging, V_{TS} Rising		2000	2100	2200	mV
$V_{HYS(COLD)}$	Hysteresis on low trip point	Battery charging, V_{TS} Falling from V_{COLD}			300		mV
$t_{DGL(TS)}$	Deglitch time, pack temperature fault detection	TS fault detected to charger disable			50		ms
$V_{DIS(TS)}$	TS function disable threshold (BQ24072, BQ24073)	TS unconnected			V_{IN} - 200mV		V
THERMAL REGULATION							
$T_{J(REG)}$	Temperature regulation limit				125		°C
$T_{J(OFF)}$	Thermal shutdown temperature	T_J Rising			155		°C
$T_{J(OFF-HYS)}$	Thermal shutdown hysteresis				20		°C

8.5 Electrical Characteristics (continued)

Over junction temperature range (0° ≤ T_J ≤ 125°C) and the recommended supply voltage range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
LOGIC LEVELS ON EN1, EN2, $\overline{CE}$, SYSOFF, TD						
V_{IL}	Logic LOW input voltage		0		0.4	V
V_{IH}	Logic HIGH input voltage		1.4		6	V
I_{IL}	Input sink current	V_{IL}= 0 V			1	μA
I_{IH}	Input source current	V_{IH}= 1.4 V			10	μA
LOGIC LEVELS ON $\overline{PGOOD}$, $\overline{CHG}$						
V_{OL}	Output LOW voltage	I_{SINK} = 5 mA			0.4	V

(1) These numbers set trip points of 0°C and 50°C while charging, with 3°C hysteresis on the trip points, with a Vishay Type 2 curve NTC with an R25 of 10 kΩ.

8.6 Typical Characteristics

V_{IN} = 6 V, EN1=1, EN2=0, BQ24073 application circuit, T_A = 25°C, unless otherwise noted.

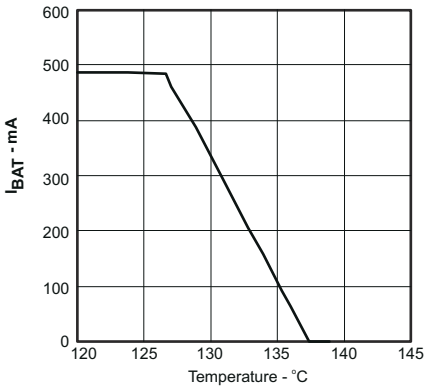


图 8-1. Thermal Regulation

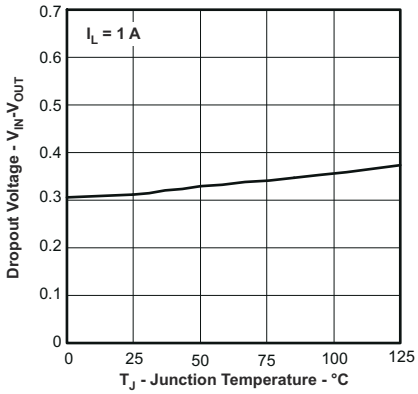


图 8-2. Dropout Voltage vs Temperature

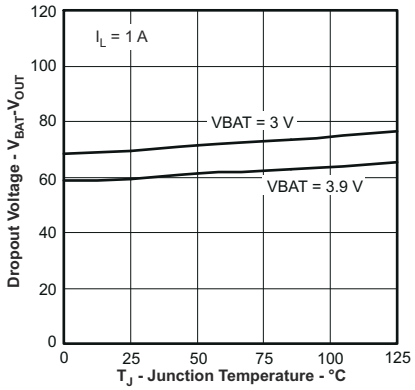


图 8-3. Dropout Voltage vs Temperature No Input Supply

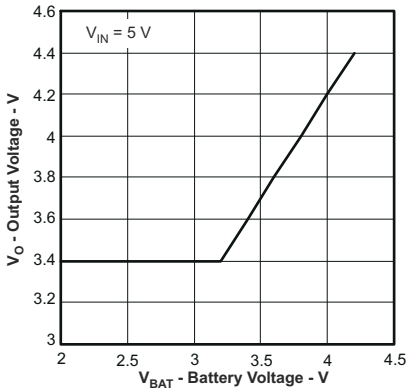


图 8-4. BQ24072 Output Regulation Voltage vs Battery Voltage

8.6 Typical Characteristics (continued)

V_{IN} = 6 V, EN1=1, EN2=0, BQ24073 application circuit, T_A = 25°C, unless otherwise noted.

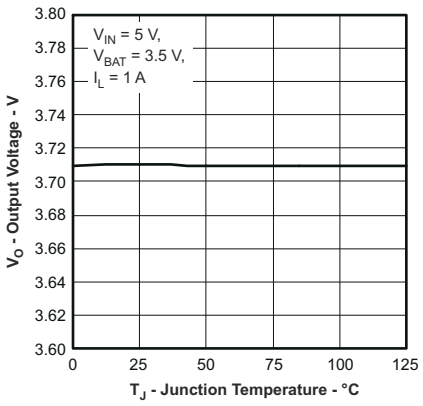


图 8-5. BQ24072 Output Regulation Voltage vs Temperature

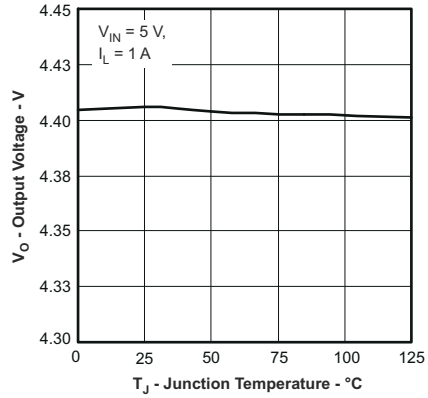


图 8-6. BQ24073/ 74 Output Regulation Voltage vs Temperature

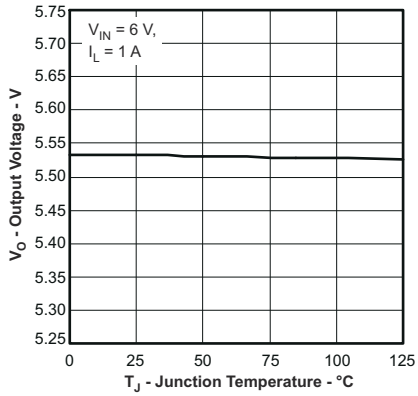


图 8-7. BQ24075, BQ24079 Output Regulation Voltage vs Temperature

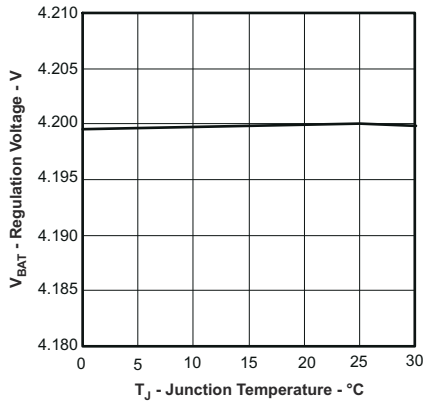


图 8-8. BAT Regulation Voltage vs Temperature

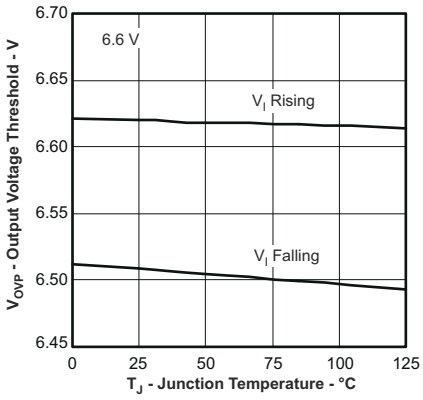


图 8-9. BQ24072/ 73/ 75/ 79 Overvoltage Protection Threshold vs Temperature

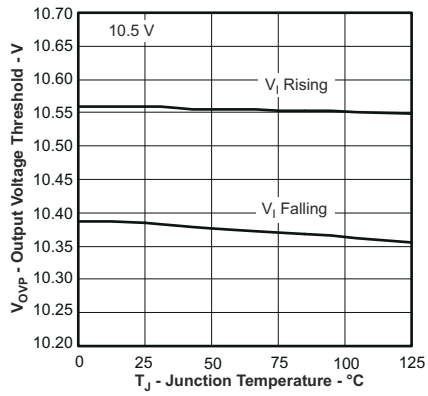


图 8-10. BQ24074 Overvoltage Protection Threshold vs Temperature

8.6 Typical Characteristics (continued)

V_{IN} = 6 V, EN1=1, EN2=0, BQ24073 application circuit, T_A = 25°C, unless otherwise noted.

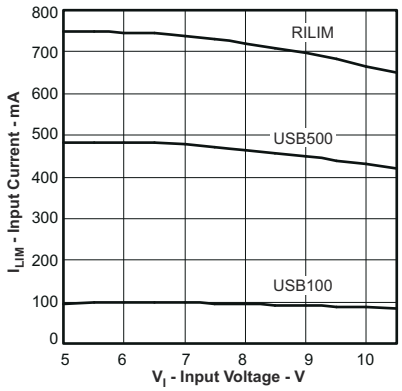


图 8-11. BQ24074 Input Current Limit vs Input Voltage

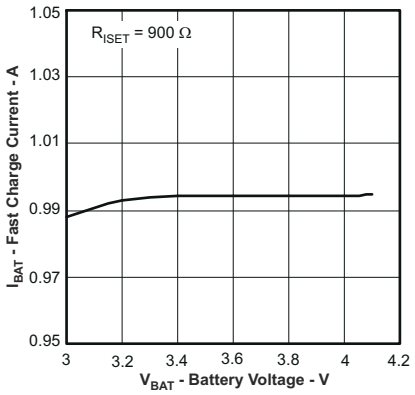


图 8-12. Fastcharge Current vs Battery Voltage

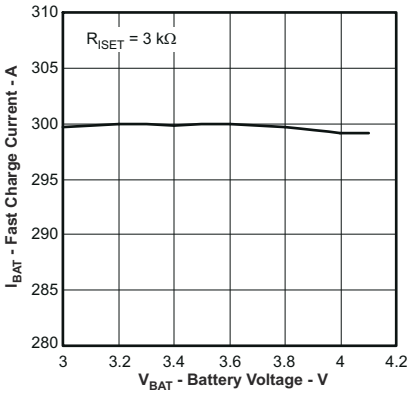


图 8-13. Fastcharge Current vs Battery Voltage

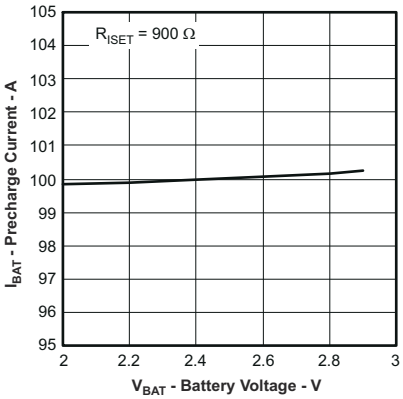


图 8-14. Precharge Current vs Battery Voltage

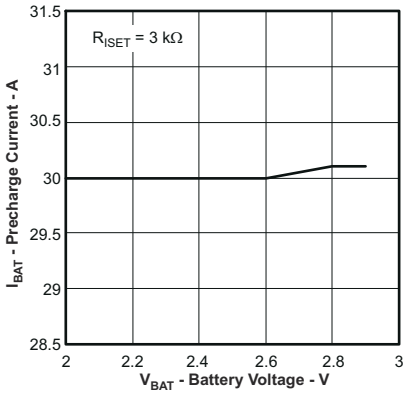


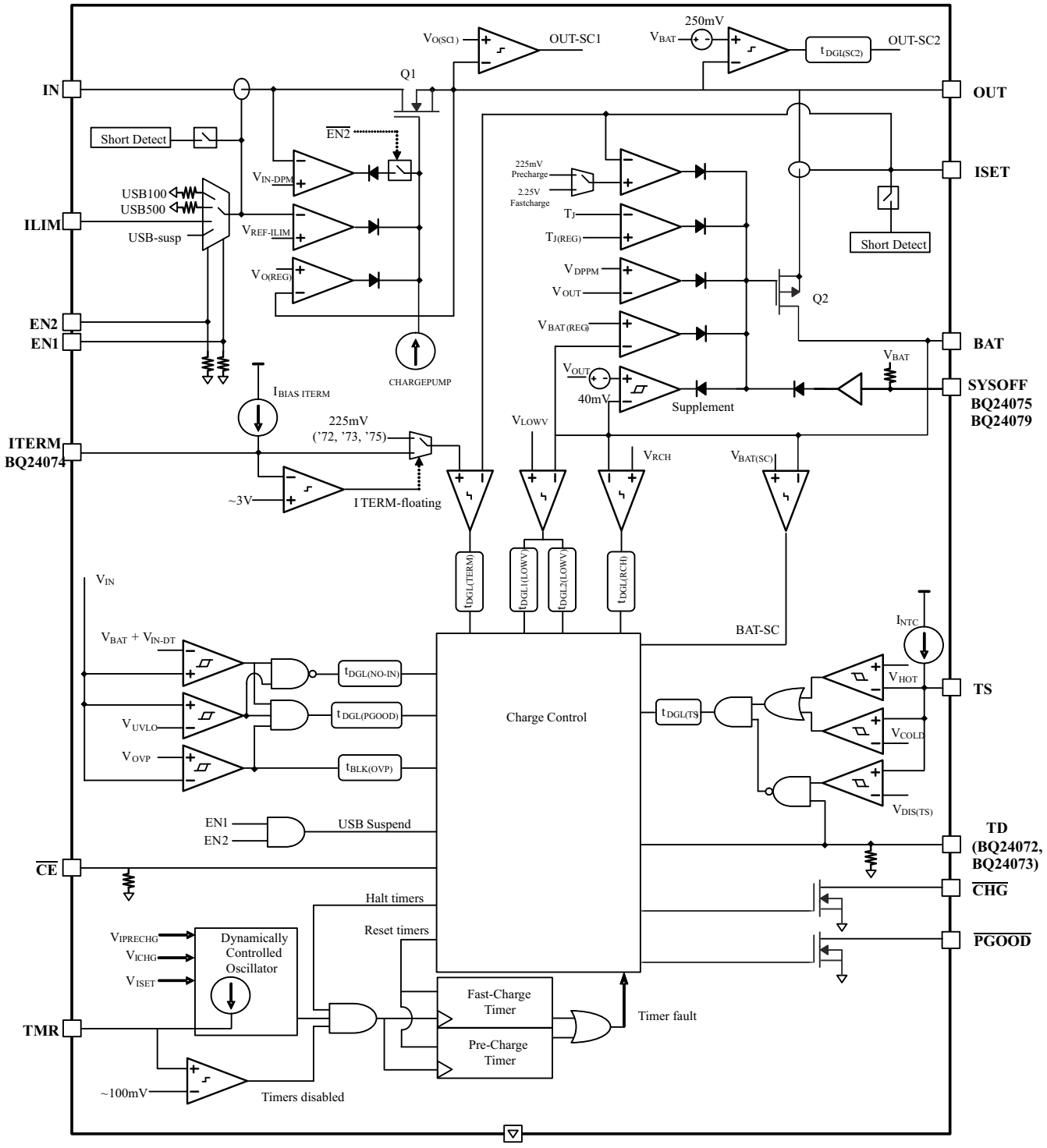
图 8-15. Precharge Current vs Battery Voltage

9 Detailed Description

9.1 Overview

The BQ2407x devices are integrated Li-Ion linear chargers and system power path management devices targeted at space-limited portable applications. The device powers the system while simultaneously and independently charging the battery. This feature reduces the number of charge and discharge cycles on the battery, allows for proper charge termination and enables the system to run with a defective or absent battery pack. This feature also allows instant system turn-on even with a totally discharged battery. The input power source for charging the battery and running the system can be an AC adapter or a USB port. The devices feature Dynamic Power Path Management (DPPM), which shares the source current between the system and battery charging, and automatically reduces the charging current if the system load increases. When charging from a USB port, the input dynamic power management (V_{IN-DPM}) circuit reduces the input current if the input voltage falls below a threshold, thus preventing the USB port from crashing. The power-path architecture also permits the battery to supplement the system current requirements when the adapter cannot deliver the peak system currents.

9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 Undervoltage Lockout (UVLO)

The BQ2407X family remains in power down mode when the input voltage at the IN pin is below the undervoltage threshold (UVLO).

During the power down mode the host commands at the control inputs ($\overline{CE}$, EN1 and EN2) are ignored. The Q1 FET connected between IN and OUT pins is off, and the status outputs $\overline{CHG}$ and $\overline{PGOOD}$ are high impedance. The Q2 FET that connects BAT to OUT is ON. (If SYSOFF is high, Q2 is off). During power down mode, the $V_{OUT(SC2)}$ circuitry is active and monitors for overload conditions on OUT.

9.3.2 Power On

When V_{IN} exceeds the UVLO threshold, the BQ2407x powers up. While V_{IN} is below V_{BAT} + $V_{IN(DT)}$, the host commands at the control inputs ($\overline{CE}$, EN1 and EN2) are ignored. The Q1 FET connected between IN and OUT pins is off, and the status outputs $\overline{CHG}$ and $\overline{PGOOD}$ are high impedance. The Q2 FET that connects BAT to OUT is ON. (If SYSOFF is high, Q2 is off). During this mode, the $V_{OUT(SC2)}$ circuitry is active and monitors for overload conditions on OUT.

Once V_{IN} rises above V_{BAT} + $V_{IN(DT)}$, $\overline{PGOOD}$ is driven low to indicate the valid power status and the $\overline{CE}$, EN1, and EN2 inputs are read. The device enters standby mode if (EN1 = EN2 = HI) or if an input overvoltage condition occurs. In standby mode, Q1 is OFF and Q2 is ON so OUT is connected to the battery input. (If SYSOFF is high, FET Q2 is off). During this mode, the $V_{OUT(SC2)}$ circuitry is active and monitors for overload conditions on OUT.

When the input voltage at IN is within the valid range: V_{IN} > UVLO ***AND*** V_{IN} > V_{BAT} + $V_{IN(DT)}$ ***AND*** V_{IN} < V_{OVP}, and the EN1 and EN2 pins indicate that the USB suspend mode is not enabled [(EN1, EN2) ≠ (HI, HI)] all internal timers and other circuit blocks are activated. The device then checks for short-circuits at the ISET and ILIM pins. If no short conditions exists, the device switches on the input FET Q1 with a 100mA current limit to checks for a short circuit at OUT. When V_{OUT} is above $V_{O(SC1)}$, the FET Q1 switches to the current limit threshold set by EN1, EN2 and R_{ILIM} and the device enters into the normal operation. During normal operation, the system is powered by the input source (Q1 is regulating), and the device continuously monitors the status of $\overline{CE}$, EN1 and EN2 as well as the input voltage conditions.

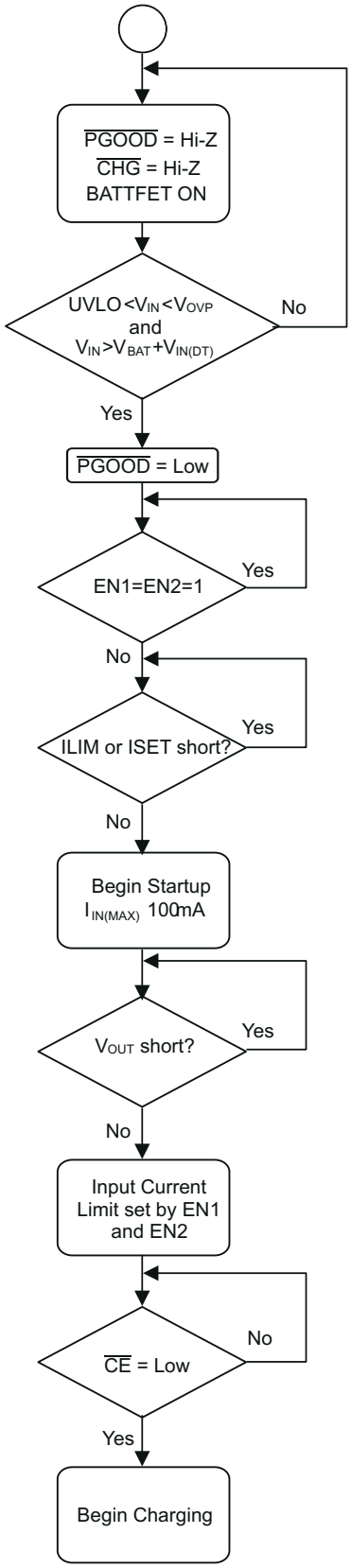


图 9-1. Startup Flow Diagram

9.3.3 Overvoltage Protection (OVP)

The BQ2407x accepts inputs up to 28 V without damage. Additionally, an overvoltage protection (OVP) circuit is implemented that shuts off the internal LDO and discontinues charging when V_{IN} > V_{OVP} for a period long than $t_{DGL(OVP)}$. When in OVP, the system output (OUT) is connected to the battery and $\overline{PGOOD}$ is high impedance. Once the OVP condition is removed, a new power on sequence starts (see 节 9.3.2). The safety timers are reset and a new charge cycle will be indicated by the $\overline{CHG}$ output.

9.3.4 Dynamic Power Path Management

The BQ2407x features an OUT output that powers the external load connected to the battery. This output is active whenever a source is connected to IN or BAT. The following sections discuss the behavior of OUT with a source connected to IN to charge the battery and a battery source only.

9.3.4.1 Input Source Connected (ADAPTER or USB)

With a source connected, the dynamic power path management (DPPM) circuitry of the BQ2407x monitors the input current continuously. The OUT output for the BQ24073/ 74/ 75/ 79 is regulated to a fixed voltage ($V_{O(REG)}$). For the BQ24072, OUT is regulated to 200 mV above the voltage at BAT. When the BAT voltage falls below 3.2 V, OUT is clamped to 3.4 V. This allows for proper startup of the system load even with a discharged battery. The current into IN is shared between charging the battery and powering the system load at OUT. The BQ2407x has internal selectable current limits of 100 mA (USB100) and 500 mA (USB500) for charging from USB ports, as well as a resistor-programmable input current limit.

The BQ2407x is USB IF compliant for the inrush current testing. The USB specification allows up to 10 μF to be hard started, which establishes 50 μC as the maximum inrush charge value when exceeding 100 mA. The input current limit for the BQ2407x prevents the input current from exceeding this limit, even with system capacitances greater than 10 μF. The input capacitance to the device must be selected small enough to prevent a violation (<10 μF), as this current is not limited. 图 9-2 demonstrates the start-up of the BQ2407x and compares it to the USB-IF specification.

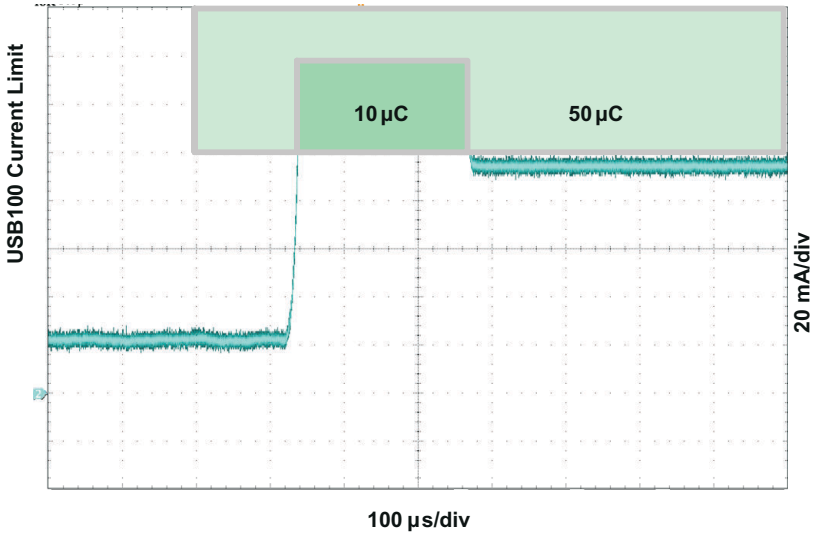


图 9-2. USB-IF Inrush Current Test

The input current limit selection is controlled by the state of the EN1 and EN2 pins as shown in the EN1/EN2 Settings table in 节 7. When using the resistor-programmable current limit, the input current limit is set by the value of the resistor connected from the ILIM pin to VSS, and is given by the equation:

$$I_{IN\text{-}MAX} = K_{ILIM}/R_{ILIM} \quad (1)$$

The input current limit is adjustable up to 1.5 A. The valid resistor range is 1.1 kΩ to 8 kΩ.

When the IN source is connected, priority is given to the system load. The DPPM and Battery Supplement modes are used to maintain the system load. 图 9-4 and 图 9-5 illustrate examples of the DPPM and supplement modes. These modes are explained in detail in the following sections.

9.3.4.1.1 Input DPM Mode (V_{IN}-DPM)

The BQ2407x utilizes the V_{IN}-DPM mode for operation from current-limited USB ports. When EN1 and EN2 are configured for USB100 (EN2=0, EN1=0) or USB500 (EN2=0, EN1=1) modes, the input voltage is monitored. If V_{IN} falls to V_{IN-DPM}, the input current limit is reduced to prevent the input voltage from falling further. This prevents the BQ2407x from crashing poorly designed or incorrectly configured USB sources. 图 9-3 shows the V_{IN}-DPM behavior to a current limited source. In this figure, the input source has a 400-mA current limit and the device is in USB500 mode (EN1=1, EN2=0).

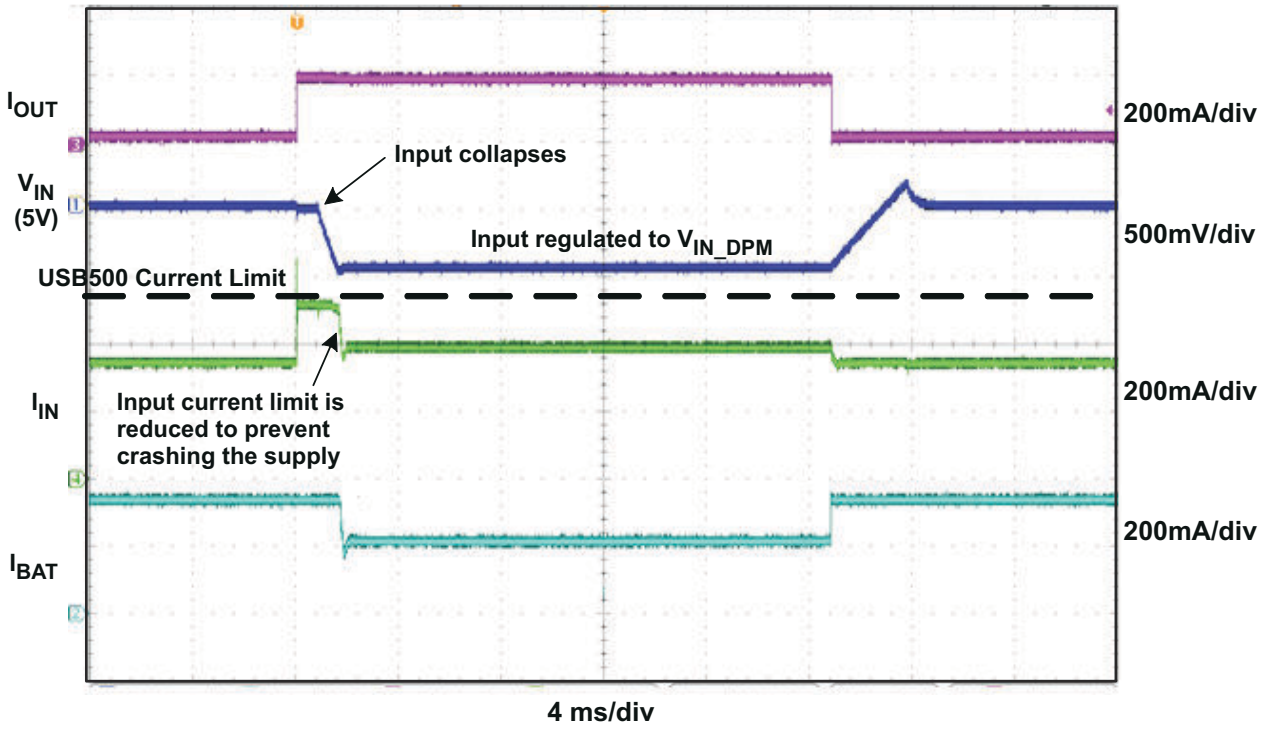


图 9-3. V_{IN}-DPM Waveform

9.3.4.1.2 DPPM Mode

When the sum of the charging and system load currents exceeds the maximum input current (programmed with EN1, EN2, and ILIM pins), the voltage at OUT decreases. Once the voltage on the OUT pin falls to V_{DPPM}, the BQ2407x enters DPPM mode. In this mode, the charging current is reduced as the OUT current increases in order to maintain the system output. Battery termination is disabled while in DPPM mode.

9.3.4.1.3 Battery Supplement Mode

While in DPPM mode, if the charging current falls to zero and the system load current increases beyond the programmed input current limit, the voltage at OUT reduces further. When the OUT voltage drops below the V_{BSUP1} threshold, the battery supplements the system load. The battery stops supplementing the system load when the voltage at OUT rises above the V_{BSUP2} threshold.

During supplement mode, the battery supplement current is not regulated (BAT-FET is fully on), however there is a short circuit protection circuit built in. 图 10-6 demonstrates supplement mode. If during battery supplement mode, the voltage at OUT drops $V_{O(SC2)}$ below the BAT voltage, the OUT output is turned off if the overload exists after $t_{DGL(SC2)}$. The short circuit recovery timer then starts counting. After $t_{REC(SC2)}$, OUT turns on and attempts to restart. If the short circuit remains, OUT is turned off and the counter restarts. Battery termination is disabled while in supplement mode.

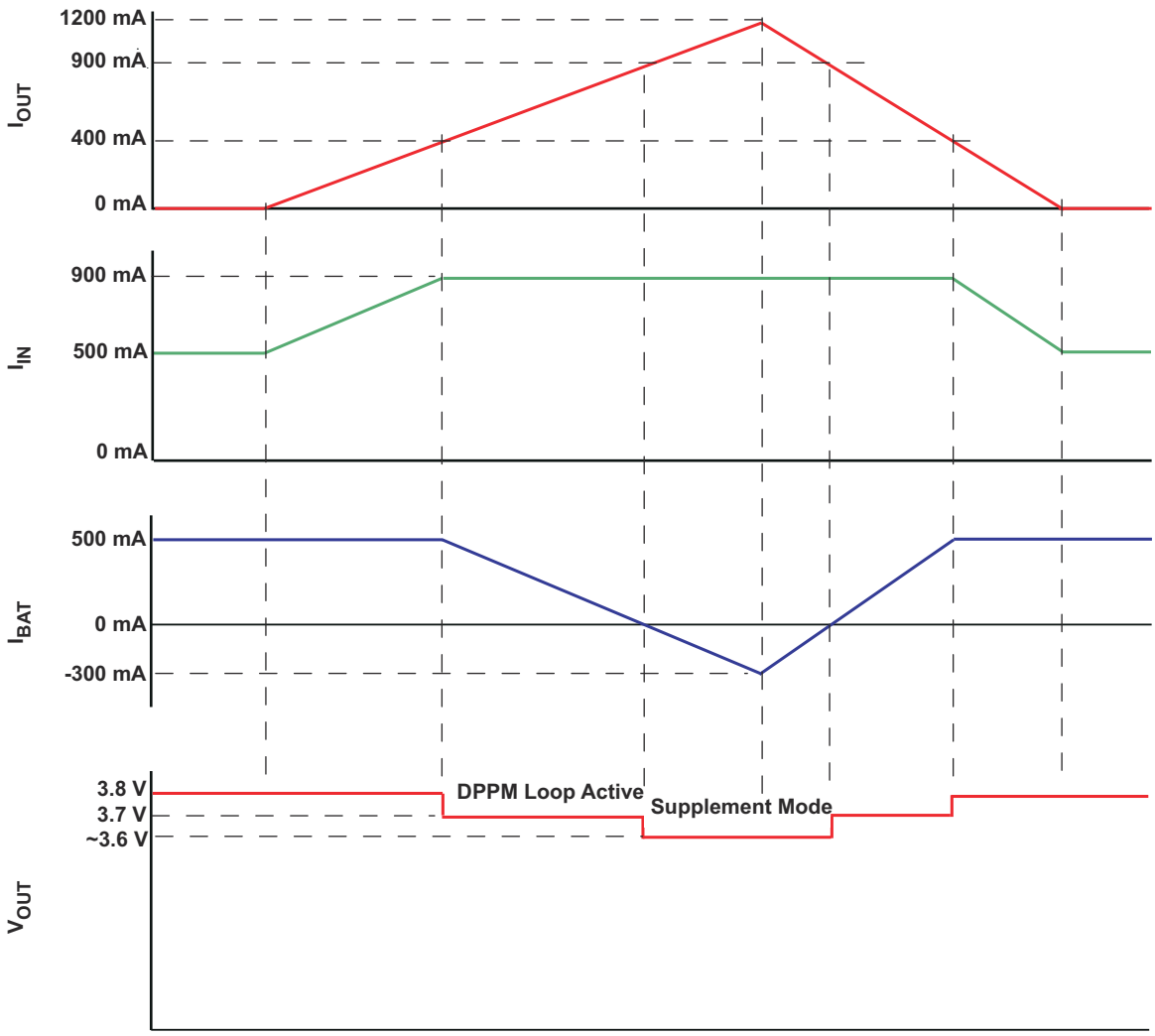


图 9-4. BQ24072 DPPM and Battery Supplement Modes (V_{OREG} = V_{BAT} + 225 mV, V_{BAT} = 3.6 V)

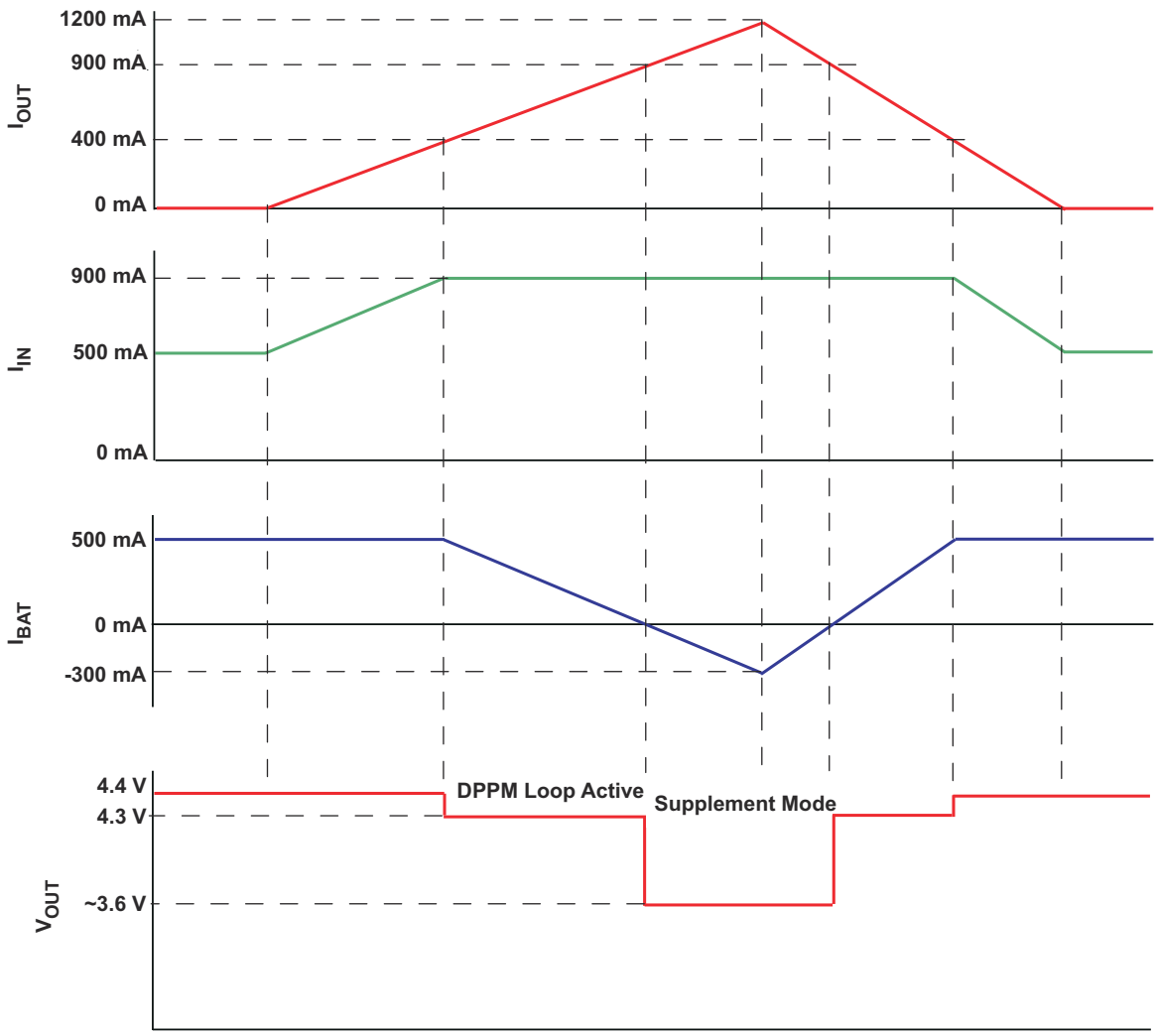


图 9-5. BQ24073 DPPM and Battery Supplement Modes (V_{OREG} = 4.4 V, V_{BAT} = 3.6 V)

9.3.4.2 Input Source Not Connected

When no source is connected to the IN input, OUT is powered strictly from the battery. During this mode the current into OUT is not regulated, similar to *Battery Supplement Mode*, however the short circuit circuitry is active. If the OUT voltage falls below the BAT voltage by 250 mV for longer than $t_{DGL(SC2)}$, OUT is turned off. The short circuit recovery timer then starts counting. After $t_{REC(SC2)}$, OUT turns on and attempts to restart. If the short circuit remains, OUT is turned off and the counter restarts. This ON/OFF cycle continues until the overload condition is removed.

9.3.5 Battery Charging

Set $\overline{CE}$ low to initiate battery charging. First, the device checks for a short-circuit on the BAT pin by sourcing $I_{BAT(SC)}$ to the battery and monitoring the voltage. When the BAT voltage exceeds $V_{BAT(SC)}$, the battery charging continues. The battery is charged in three phases: conditioning pre-charge, constant current fast charge (current regulation) and a constant voltage tapering (voltage regulation). In all charge phases, an internal control loop monitors the IC junction temperature and reduces the charge current if an internal temperature threshold is exceeded.

图 9-6 illustrates a normal Li-Ion charge cycle using the BQ2407x:

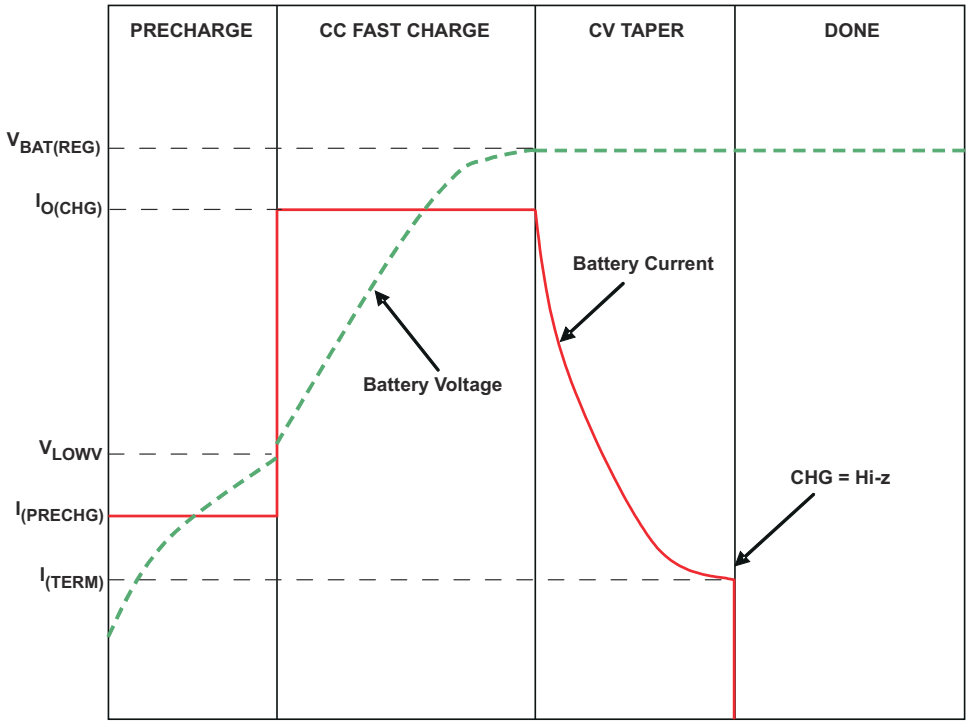


图 9-6. Typical Charge Cycle

In the pre-charge phase, the battery is charged at with the pre-charge current (I_{PRECHG}). Once the battery voltage crosses the V_{LOWV} threshold, the battery is charged with the fast-charge current (I_{CHG}). As the battery voltage reaches $V_{BAT(REG)}$, the battery is held at a constant voltage of $V_{BAT(REG)}$ and the charge current tapers off as the battery approaches full charge. When the battery current reaches I_{TERM}, the $\overline{CHG}$ pin indicates *charging done* by going high-impedance.

Note that termination detection is disabled whenever the charge rate is reduced because of the actions of the thermal loop, the DPPM loop or the V_{IN-DPM} loop.

The value of the fast-charge current is set by the resistor connected from the ISET pin to VSS, and is given by the equation:

$$I_{CHG} = K_{ISET}/R_{ISET} \quad (2)$$

The charge current limit is adjustable up to 1.5 A. The valid resistor range is 590 Ω to 8.9 kΩ. If I_{CHG} is programmed as greater than the input current limit, the battery will not charge at the rate of I_{CHG}, but at the slower rate of $I_{IN(MAX)}$ (minus the load current on the OUT pin, if any). In this case, the charger timers will be proportionately slowed down.

9.3.5.1 Charge Current Translator

When the charger is enabled, internal circuits generate a current proportional to the charge current at the ISET input. The current out of ISET is 1/400 (±10%) of the charge current. This current, when applied to the external charge current programming resistor, R_{ISET}, generates an analog voltage that can be monitored by an external host to calculate the current sourced from BAT.

$$V_{ISET} = I_{CHARGE} / 400 \times R_{ISET} \quad (3)$$

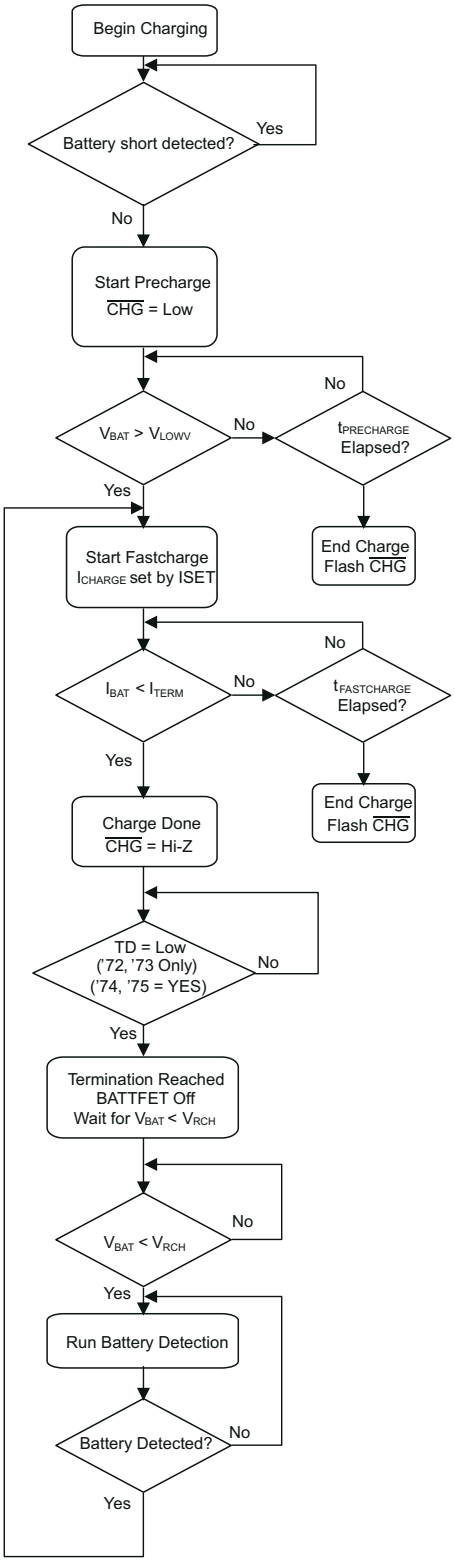


图 9-7. Battery Charging Flow Diagram

9.3.5.2 Adjustable Termination Threshold (ITERM Input, BQ24074)

The termination current threshold in the BQ24074 is user-programmable. Set the termination current by connecting a resistor from ITERM to VSS. For USB100 mode (EN1 = EN2 = Low), the termination current value is calculated as:

$$I_{TERM} = 0.01 \times R_{ITERM} / R_{ISET} \quad (4)$$

In the other input current limit modes (EN1 ≠ EN2), the termination current value is calculated as:

$$I_{TERM} = 0.03 \times R_{ITERM} / R_{ISET} \quad (5)$$

The termination current is programmable up to 50% of the fastcharge current. The R_{ITERM} resistor must be less than 15 kΩ. Leave ITERM unconnected to select the default internally set termination current.

9.3.5.3 Termination Disable (TD Input, BQ24072, BQ24073)

The BQ24072 and BQ24073 contain a TD input that allows termination to be enabled/ disabled. Connect TD to a logic high to disable charge termination. When termination is disabled, the device goes through the pre-charge, fast-charge and CV phases, then remains in the CV phase. During the CV phase, the charger maintains the output voltage at BAT equal to $V_{BAT(REG)}$, and charging current does not terminate. The charge current is set by I_{CHG} or I_{IN}max, whichever is less. Battery detection is not performed. The $\overline{CHG}$ output is high impedance once the current falls below I_{TERM} and does not go low until the input power or $\overline{CE}$ are toggled. When termination is disabled, the pre-charge and fast-charge safety timers are also disabled. Battery pack temperature sensing (TS pin functionality) is disabled if the TD pin is high and the TS pin is unconnected or pulled up to V_{IN}.

9.3.5.4 Battery Detection and Recharge

The BQ2407x automatically detects if a battery is connected or removed. Once a charge cycle is complete, the battery voltage is monitored. When the battery voltage falls below V_{RCH}, the battery detection routine is run. During battery detection, current ($I_{BAT(DET)}$) is pulled from the battery for a duration t_{DET} to see if the voltage on BAT falls below V_{LOWV}. If not, charging begins. If it does, then it indicates that the battery is missing or the protector is open. Next, the precharge current is applied for t_{DET} to close the protector if possible. If $V_{BAT} < V_{RCH}$, then the protector closed and charging is initiated. If $V_{BAT} > V_{RCH}$, then the battery is determined to be missing and the detection routine continues.

9.3.5.5 Battery Disconnect (SYSOFF Input, BQ24075, BQ24079)

The BQ24075 and BQ24079 feature a SYSOFF input that allows the user to turn the FET Q2 off and disconnect the battery from the OUT pin. This is useful for disconnecting the system load from the battery, factory programming where the battery is not installed or for host side impedance track fuel gauging, such as bq27500, where the battery open circuit voltage level must be detected before the battery charges or discharges. The /CHG output remains low when SYSOFF is high. Connect SYSOFF to VSS, to turn Q2 on for normal operation. SYSOFF is internally pulled to VBAT through ~5 MΩ resistor.

9.3.5.6 Dynamic Charge Timers (TMR Input)

The BQ2407x devices contain internal safety timers for the pre-charge and fast-charge phases to prevent potential damage to the battery and the system. The timers begin at the start of the respective charge cycles. The timer values are programmed by connecting a resistor from TMR to VSS. The resistor value is calculated using the following equation:

$$t_{PRECHG} = K_{TMR} \times R_{TMR} \quad (6)$$

$$t_{MAXCHG} = 10 \times K_{TMR} \times R_{TMR} \quad (7)$$

Leave TMR unconnected to select the internal default timers. Disable the timers by connecting TMR to VSS.

Reset the timers by toggling the CE pin, or by toggling EN1, EN2 pin to put the device in and out of USB suspend mode (EN1 = HI, EN2 = HI).

Note that timers are suspended when the device is in thermal shutdown, and the timers are slowed proportionally to the charge current when the device enters thermal regulation. For the BQ24072 and BQ24073, the timers are disabled when TD is connected to a high logic level.

During the fast charge phase, several events increase the timer durations.

- The system load current activates the DPPM loop which reduces the available charging current
- The input current is reduced because the input voltage has fallen to V_{IN-DPM}
- The device has entered thermal regulation because the IC junction temperature has exceeded $T_{J(REG)}$

During each of these events, the internal timers are slowed down proportionately to the reduction in charging current. For example, if the charging current is reduced by half for two minutes, the timer clock is reduced to half the frequency and the counter counts half as fast resulting in only one minute of "counting" time.

If the pre charge timer expires before the battery voltage reaches V_{LOWV}, the BQ2407x indicates a fault condition. Additionally, if the battery current does not fall to I_{TERM} before the fast charge timer expires, a fault is indicated. The $\overline{CHG}$ output flashes at approximately 2 Hz to indicate a fault condition. The fault condition is cleared by toggling $\overline{CE}$ or the input power, entering/ exiting USB suspend mode, or an OVP event.

9.3.5.7 Status Indicators ($\overline{PGOOD}$, $\overline{CHG}$)

The BQ2407x contains two open-drain outputs that signal its status. The $\overline{PGOOD}$ output signals when a valid input source is connected. $\overline{PGOOD}$ is low when $(V_{BAT} + V_{IN(DT)}) < V_{IN} < V_{OVP}$. When the input voltage is outside of this range, $\overline{PGOOD}$ is high impedance.

The charge cycle after power-up, CE going low, or exiting OVP is indicated with the $\overline{CHG}$ pin on (low - LED on), whereas all refresh (subsequent) charges will result in the $\overline{CHG}$ pin off (open - LED off). In addition, the $\overline{CHG}$ signals timer faults by flashing at approximately 2 Hz.

表 9-1. $\overline{PGOOD}$ Status Indicator

INPUT STATE	$\overline{PGOOD}$ OUTPUT
$V_{IN} < V_{UVLO}$	High-impedance
$V_{UVLO} < V_{IN} < V_{BAT} + V_{IN(DT)}$	High-impedance
$V_{BAT} + V_{IN(DT)} < V_{IN} < V_{OVP}$	Low
$V_{IN} > V_{OVP}$	High-impedance

表 9-2. $\overline{CHG}$ Status Indicator

CHARGE STATE	$\overline{CHG}$ OUTPUT
Charging	Low (for first charge cycle)
Charging suspended by thermal loop	
Safety timers expired	Flashing at 2 Hz
Charging done	High-impedance
Recharging after termination	
IC disabled or no valid input power	
Battery absent	

9.3.5.8 Thermal Regulation and Thermal Shutdown

The BQ2407x contain a thermal regulation loop that monitors the die temperature. If the temperature exceeds $T_{J(REG)}$, the device automatically reduces the charging current to prevent the die temperature from increasing further. In some cases, the die temperature continues to rise despite the operation of the thermal loop, particularly under high VIN and heavy OUT system load conditions. Under these conditions, if the die temperature increases to $T_{J(OFF)}$, the input FET Q1 is turned OFF. FET Q2 is turned ON to ensure that the battery still powers the load on OUT. Once the device die temperature cools by $T_{J(OFF-HYS)}$, the input FET Q1 is turned on and the device returns to thermal regulation. Continuous overtemperature conditions result in a "hiccup" mode. During thermal regulation, the safety timers are slowed down proportionately to the reduction in current limit.

Note that this feature monitors the die temperature of the BQ2407x. This is not synonymous with ambient temperature. Self heating exists due to the power dissipated in the IC because of the linear nature of the battery charging algorithm and the LDO associated with OUT. A modified charge cycle with the thermal loop active is shown in 图 9-8. Battery termination is disabled during thermal regulation.

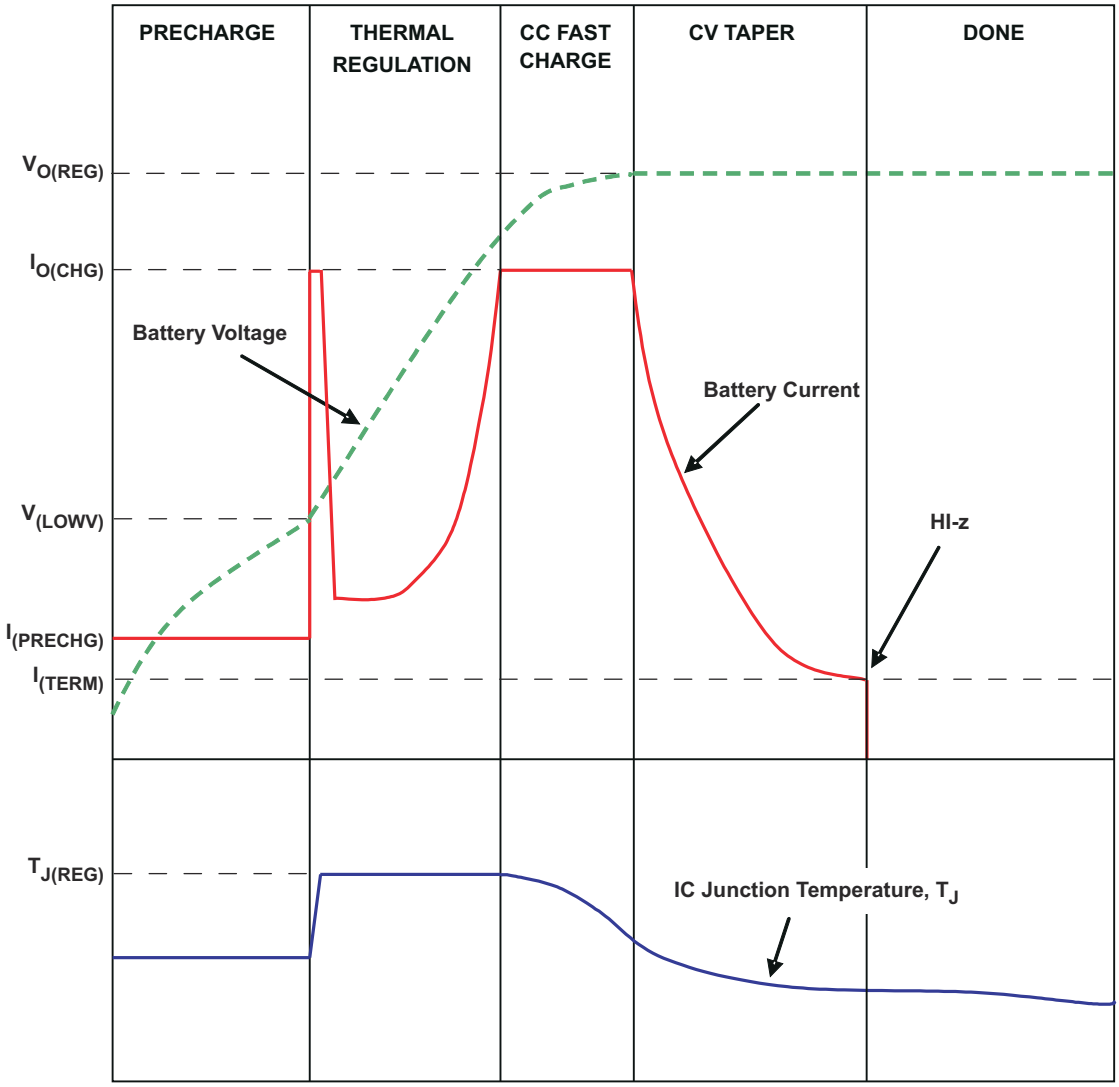


图 9-8. Charge Cycle Modified by Thermal Loop

9.3.6 Battery Pack Temperature Monitoring

The BQ2407x features an external battery pack temperature monitoring input. The TS input connects to the NTC thermistor in the battery pack to monitor battery temperature and prevent dangerous over-temperature conditions. During charging, I_{NTC} is sourced to TS and the voltage at TS is continuously monitored. If, at any time, the voltage at TS is outside of the operating range (V_{COLD} to V_{HOT}), charging is suspended. The timers maintain their values but suspend counting. When the voltage measured at TS returns to within the operation window, charging is resumed and the timers continue counting. When charging is suspended due to a battery pack temperature fault, the $\overline{CHG}$ pin remains low and continues to indicate charging.

For the BQ24072 and BQ24073, battery pack temperature sensing is disabled when termination is disabled (TD = High) and the voltage at TS is greater than $V_{DIS(TS)}$. For applications that do not require the TS monitoring function, connect a 10-kΩ resistor from TS to VSS to set the TS voltage at a valid level and maintain charging.

The allowed temperature range for 103AT-2 type thermistor is 0°C to 50°C. However, the user may increase the range by adding two external resistors. See 图 9-9 for the circuit details. The values for Rs and Rp are calculated using the following equations:

$$Rs = \frac{-(R_{TH} + R_{TC}) \pm \sqrt{\left\{(R_{TH}+R_{TC})^2 - 4\left\{R_{TH} \times R_{TC} + \frac{V_H \times V_C}{(V_H - V_C) \times I_{TS}} \times (R_{TC} - R_{TH})\right\}\right\}}}{2} \quad (8)$$

$$Rp = \frac{V_H \times (R_{TH} + R_S)}{I_{TS} \times (R_{TH} + R_S) - V_H} \quad (9)$$

where

- R_{TH}: Thermistor Hot Trip Value found in thermistor data sheet
- R_{TC}: Thermistor Cold Trip Value found in thermistor data sheet
- V_H: IC's Hot Trip Threshold = 0.3 V nominal
- V_C: IC's Cold Trip Threshold = 2.1 V nominal
- I_{TS}: IC's Output Current Bias = 75 µA nominal
- NTC Thermsitor Semitec 103AT-4

Rs and Rp 1% values were chosen closest to calculated values in 表 9-3.

表 9-3. Calculated Values

COLD TEMP RESISTANCE AND TRIP THRESHOLD; Ω (°C)	HOT TEMP RESISTANCE AND TRIP THRESHOLD; Ω (°C)	EXTERNAL BIAS RESISTOR, Rs (Ω)	EXTERNAL BIAS RESISTOR, Rp (Ω)
28000 (– 0.6)	4000 (51)	0	∞
28480 (– 1)	3536 (55)	487	845000
28480 (– 1)	3021 (60)	1000	549000
33890 (– 5)	4026 (51)	76.8	158000
33890 (– 5)	3536 (55)	576	150000
33890 (– 5)	3021 (60)	1100	140000

RHOT and RCOLD are the thermistor resistance at the desired hot and cold temperatures, respectively. The temperature window cannot be tightened more than using only the thermistor connected to TS, it can only be extended.

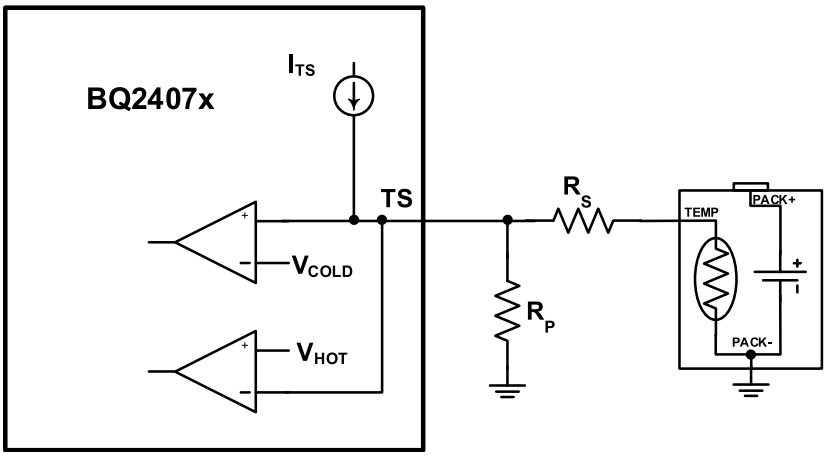


图 9-9. Extended TS Pin Thresholds

9.4 Device Functional Modes

9.4.1 Sleep Mode

When the input is between UVLO and $V_{IN(DT)}$, the device enters sleep mode. After entering sleep mode for >20 mS the internal FET connection between the IN and OUT pin is disabled and pulling the input to ground will not discharge the battery, other than the leakage on the BAT pin. If one has a full 1000-mAHr battery and the leakage is 10 μA, then it would take 1000 mAHr / 10 μA = 100000 hours (11.4 years) to discharge the battery. The self-discharge of the battery is typically five times higher than this.

9.4.2 Explanation of Deglitch Times and Comparator Hysteresis

备注

图 9-10 to 图 9-14 are not to scale.

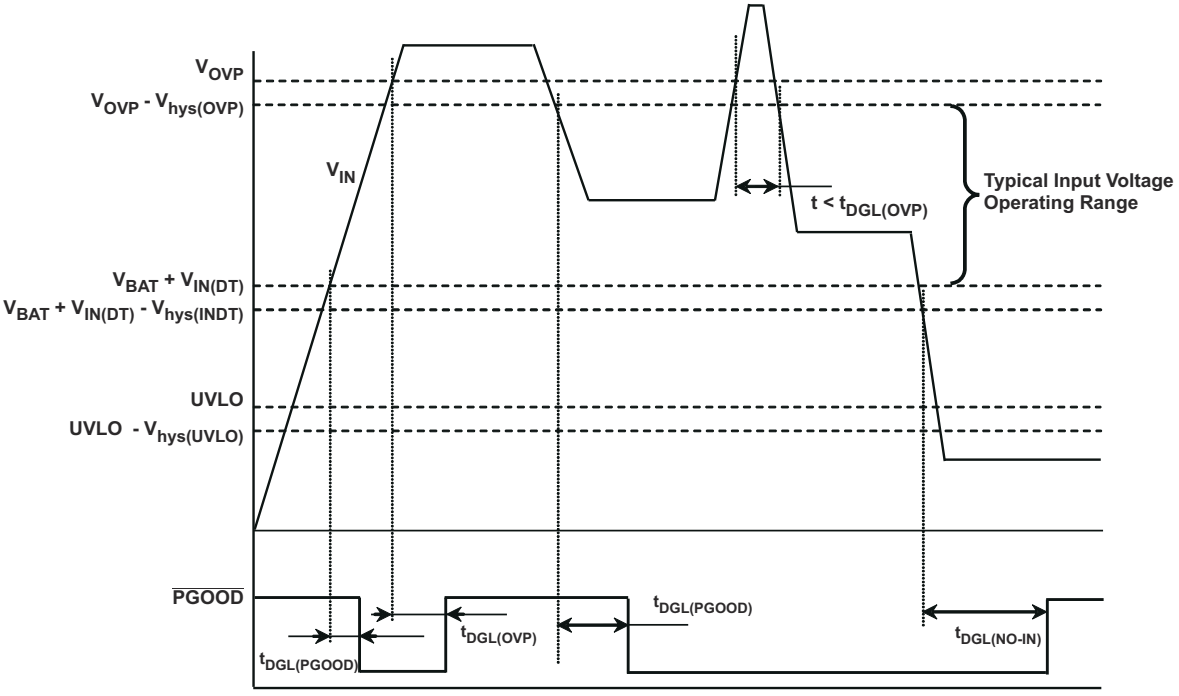


图 9-10. Power-Up, Power-Down, Power Good Indication

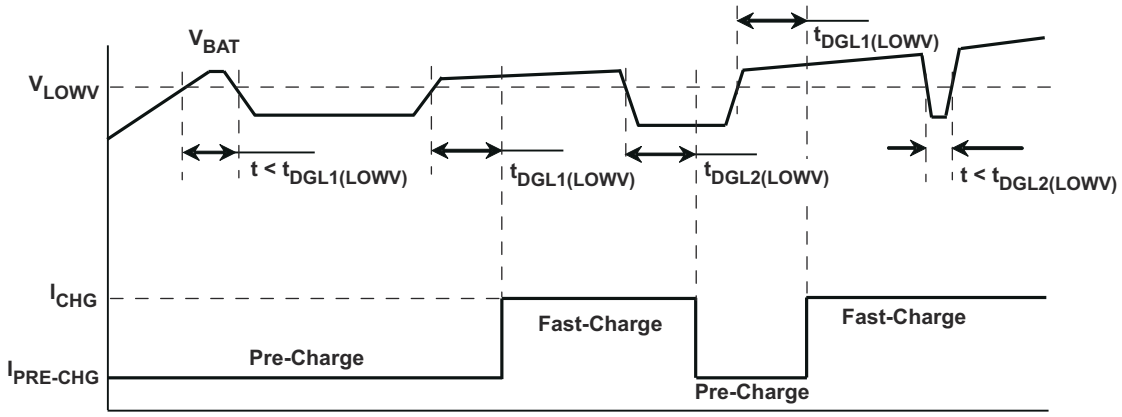


图 9-11. Precharge to Fast-Charge, Fast- to Pre-Charge Transition – $t_{DGL1(LOWV)}$, $t_{DGL2(LOWV)}$

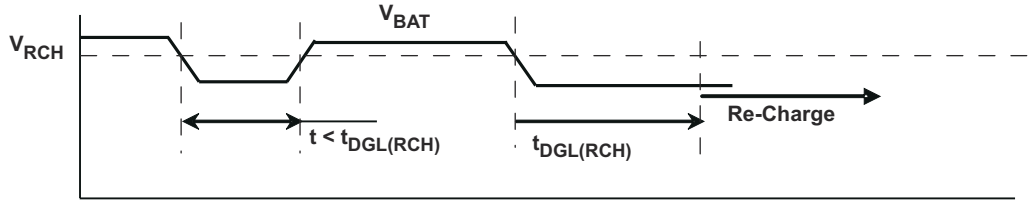


图 9-12. Recharge – $t_{DGL(RCH)}$

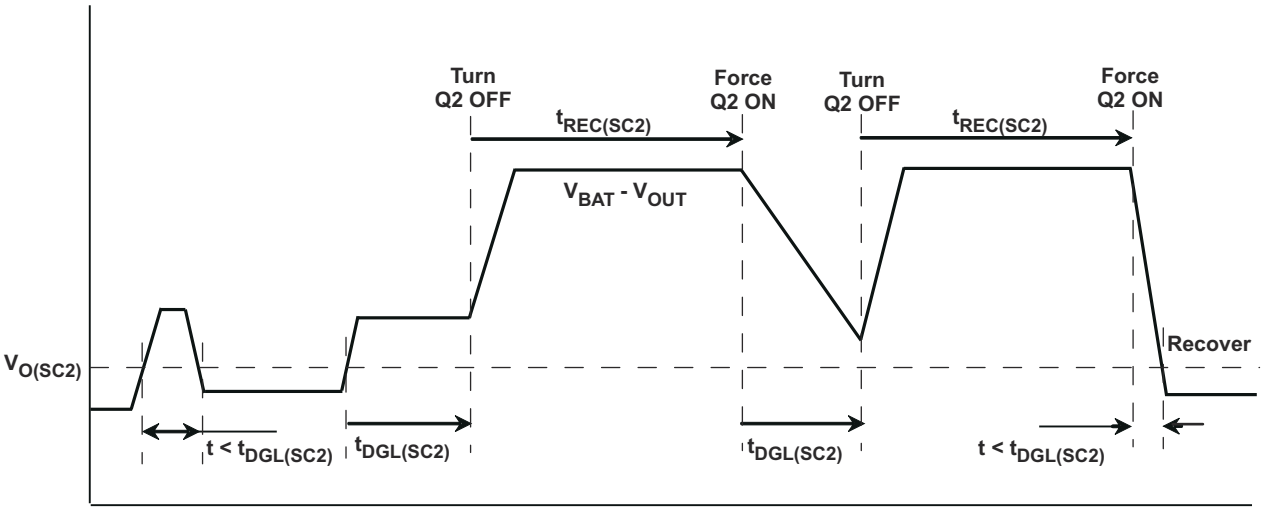


图 9-13. OUT Short-Circuit – Supplement Mode

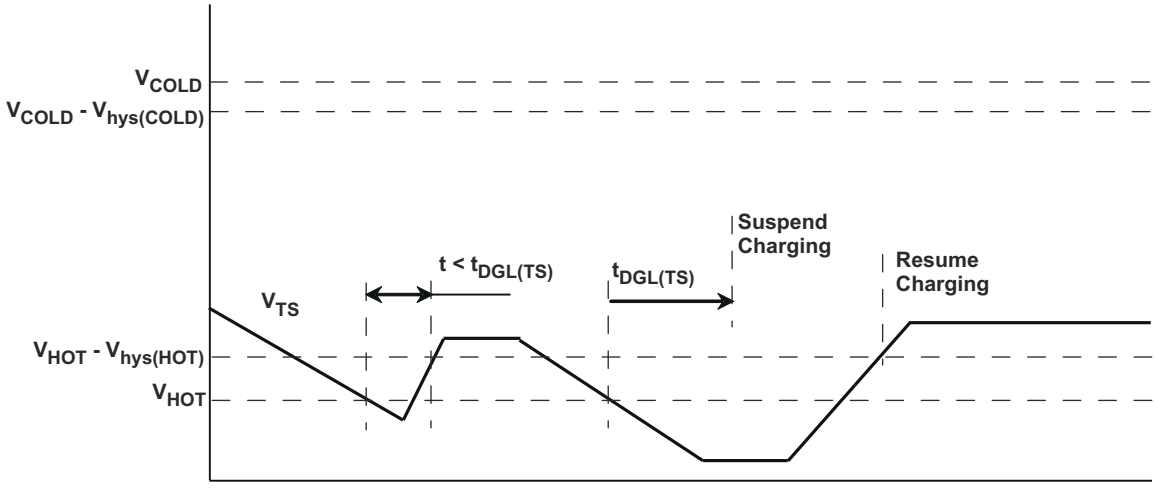


图 9-14. Battery Pack Temperature Sensing – TS Pin. Battery Temperature Increasing

10 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客 户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

10.1 Application Information

The BQ2407x devices power the system while simultaneously and independently charging the battery. The input power source for charging the battery and running the system can be an AC adapter or a USB port. The devices feature dynamic power-path management (DPPM), which shares the source current between the system and battery charging and automatically reduces the charging current if the system load increases. When charging from a USB port, the input dynamic power management (VIN-DPM) circuit reduces the input current limit if the input voltage falls below a threshold, preventing the USB port from crashing. The power-path architecture also permits the battery to supplement the system current requirements when the adapter cannot deliver the peak system currents.

The BQ2407x is configurable to be host controlled for selecting different input current limits based on the input source connected, or a fully stand alone device for applications that do not support multiple types of input sources.

10.2 Typical Application

V_{IN} = UVLO to V_{OVP}, $I_{FASTCHG}$ = 800 mA, $I_{IN(MAX)}$ = 1.3 A, Battery Temperature Charge Range = 0°C to 50°C, 6.25-hour Fastcharge Safety Timer

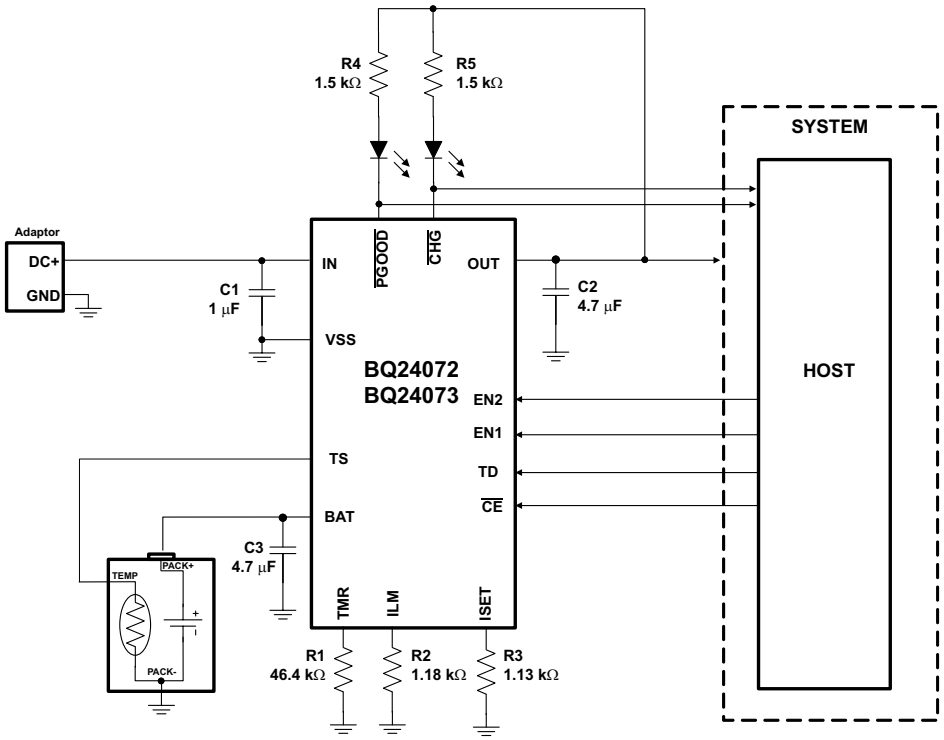


图 10-1. Using BQ24072/ BQ24073 in a Host-Controlled Charger Application

10.2.1 Design Requirements

- Supply voltage = 5 V
- Fast charge current of approximately 800 mA; ISET - pin 16
- Input Current Limit =1.3 A; ILIM - pin 12
- Termination Current Threshold = 110 mA; ITERM – pin 15 (BQ24074 only)
- Safety timer duration, Fast-Charge = 6.25 hours; TMR – pin 14
- TS – Battery Temperature Sense = 10 kΩ NTC (103AT-2)

10.2.2 Detailed Design Procedure

10.2.2.1 BQ2407x Charger Design Example

See 图 10-1 to 图 10-13 for Schematics of the Design Example.

10.2.2.1.1 Termination Disable (TD) (BQ24072, BQ24073 only)

Connect TD high to disable termination. Connect TD low to enable termination.

10.2.2.1.2 System ON/OFF (SYSOFF) (BQ24075 or BQ24079 only)

Connect SYSOFF high to disconnect the battery from the system load. Connect SYSOFF low for normal operation

10.2.2.2 Calculations

10.2.2.2.1 Program the Fast Charge Current (ISET):

$R_{ISET} = K_{ISET} / I_{CHG}$

K_{ISET} = 890 AΩ from the electrical characteristics table.

R_{ISET} = 890 AΩ / 0.8 A = 1.1125 kΩ

Select the closest standard value, which for this case is 1.13 kΩ. Connect this resistor between ISET (pin 16) and V_{SS}.

10.2.2.2.2 Program the Input Current Limit (ILIM)

$R_{ILIM} = K_{ILIM} / I_{I\_MAX}$

K_{ILIM} = 1550 AΩ from the electrical characteristics table.

R_{ISET} = 1550 AΩ / 1.3 A = 1.192 kΩ

Select the closest standard value, which for this case is 1.18 kΩ. Connect this resistor between ILIM (pin 12) and V_{SS}.

10.2.2.2.3 Program the Termination Current Threshold (I_{TERM}) (BQ24074 only)

$R_{ITERM} = I_{TERM} \times R_{ISET} / 0.030$

R_{ISET} = 1.13 kΩ from the above calculation.

R_{ITERM} = 110 mA × 1.13 kΩ / 0.030 = 4.143 kΩ

Select the closest standard value, which for this case is 4.12 kΩ. Connect this resistor between ITERM (pin 15) and V_{SS}. Note that when in USB100 mode (EN1 = EN2 = V_{SS}), the termination threshold is 1/3 of the normal threshold.

10.2.2.2.4 Program 6.25-hour Fast-Charge Safety Timer (TMR)

$R_{TMR} = t_{MAXCHG} / (10 \times K_{TMR})$

K_{TMR} = 48 s/kΩ from the electrical characteristics table.

R_{TMR} = (6.25 hr × 3600 s/hr) / (10 × 48 s/kΩ) = 46.8 kΩ

Select the closest standard value, which for this case is 46.4 kΩ. Connect this resistor between TMR (pin 14) and V_{SS}.

10.2.2.3 TS Function

Use a 10-kΩ NTC thermistor in the battery pack (103AT-2). For applications that do not require the TS monitoring function, connect a 10-kΩ resistor from TS to VSS to set the TS voltage at a valid level and maintain charging.

10.2.2.4 $\overline{CHG}$ and $\overline{PGOOD}$

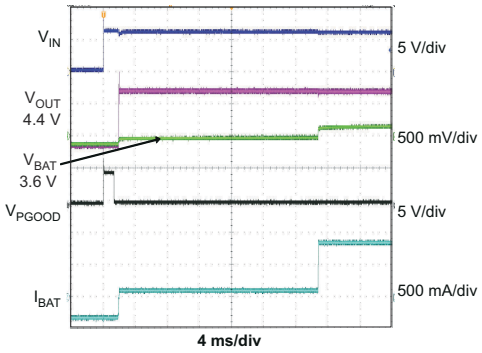
LED Status: Connect a 1.5-kΩ resistor in series with a LED between OUT and $\overline{CHG}$ to indicate charging status. Connect a 1.5-kΩ resistor in series with a LED between OUT and $\overline{PGOOD}$ to indicate when a valid input source is connected.

Processor Monitoring Status: Connect a pullup resistor (on the order of 100 kΩ) between the power rail of the processor and $\overline{CHG}$ and $\overline{PGOOD}$.

10.2.2.5 Selecting IN, OUT, and BAT Pin Capacitors

In most applications, all that is needed is a high-frequency decoupling capacitor (ceramic) on the power pin, input, output and battery pins. Using the values shown on the application diagram, is recommended. After evaluation of these voltage signals with real system operational conditions, one can determine if capacitance values can be adjusted toward the minimum recommended values (DC load application) or higher values for fast high amplitude pulsed load applications. Note if designed high input voltage sources (bad adaptors or wrong adaptors), the capacitor needs to be rated appropriately. Ceramic capacitors are tested to 2x their rated values so a 16-V capacitor may be adequate for a 30-V transient (verify tested rating with capacitor manufacturer).

10.2.3 Application Curves



R_{LOAD} = 10 Ω

图 10-2. Adapter Plug-In Battery Connected

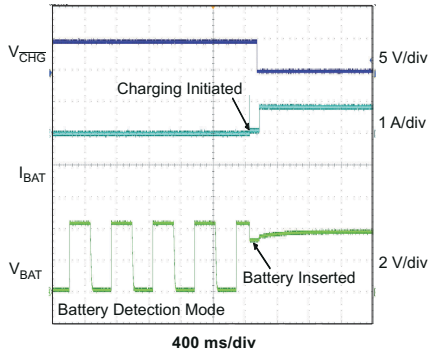


图 10-3. Battery Detection Battery Inserted

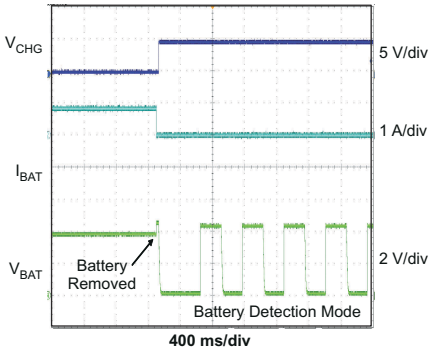
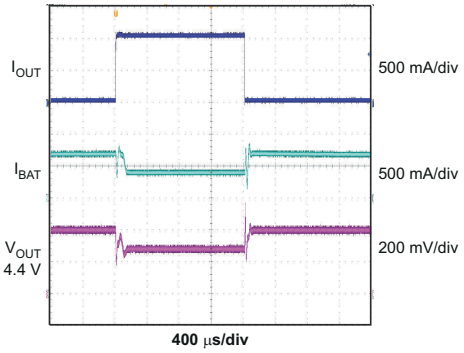
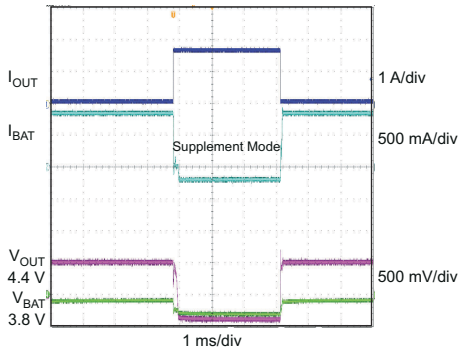


图 10-4. Battery Detection Battery Removed



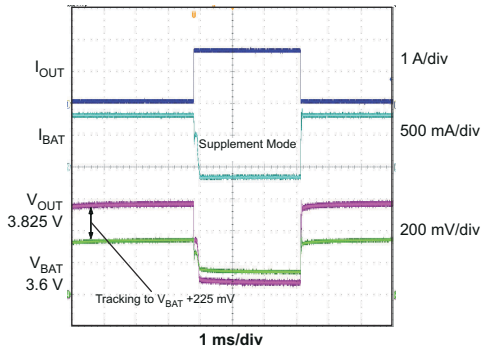
R_{LOAD} = 20 Ω to 9 Ω

图 10-5. Entering and Exiting DPPM Mode



R_{LOAD} = 25 Ω to 4.5 Ω

图 10-6. Entering and Exiting Battery Supplement Mode BQ24074



R_{LOAD} = 20 Ω to 4.5 Ω

图 10-7. Entering and Exiting Battery Supplement Mode BQ24072

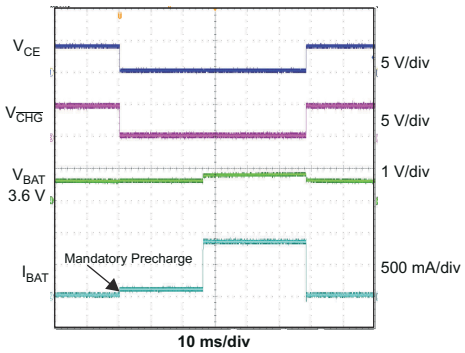
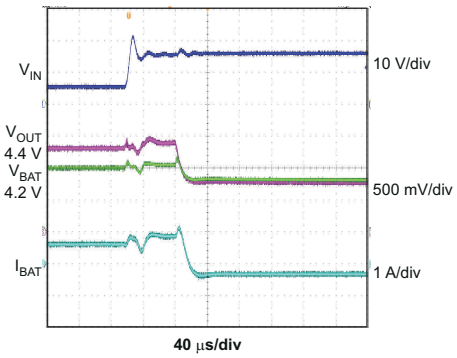


图 10-8. Charger ON/OFF Using $\overline{CE}$



V_{IN} = 6 V to 15 V R_{LOAD} = 10 Ω

图 10-9. OVP Fault

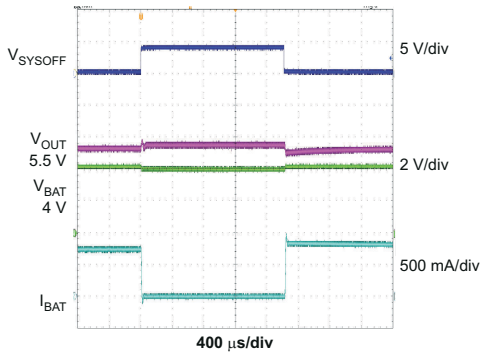


图 10-10. System ON/OFF With Input Connected V_{IN} = 6 V BQ24075, BQ24079

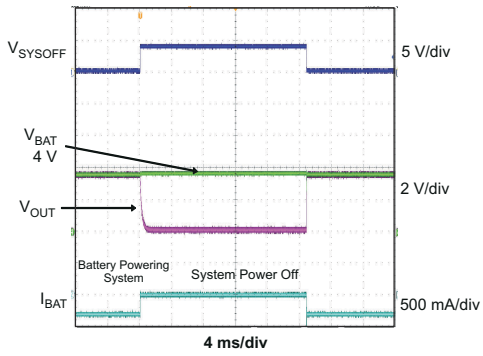


图 10-11. System ON/OFF With Input Not Connected V_{IN} = 0 V BQ24075, BQ24079

10.3 System Examples

10.3.1 Standalone Charger

V_{IN} = UVLO to V_{OVP}, $I_{FASTCHG}$ = 800 mA, $I_{IN(MAX)}$ = 1.3 A, I_{TERM} = 110 mA, Battery Temperature Charge Range = 0°C to 50°C, Safety Timers disabled.

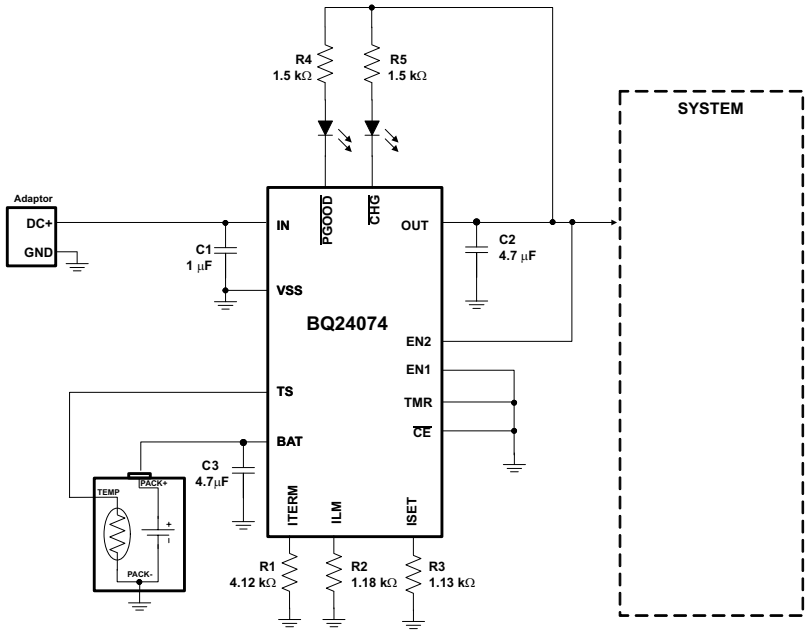


图 10-12. Using BQ24074 in a Standalone Charger Application

10.3.2 Disconnecting the Battery From the System

V_{IN} = UVLO to V_{OVP}, $I_{FASTCHG}$ = 800 mA, $I_{IN(MAX)}$ = 1.3 A, Battery Temperature Charge Range = 0°C to 50°C, 6.25 hour Fastcharge Safety Timer.

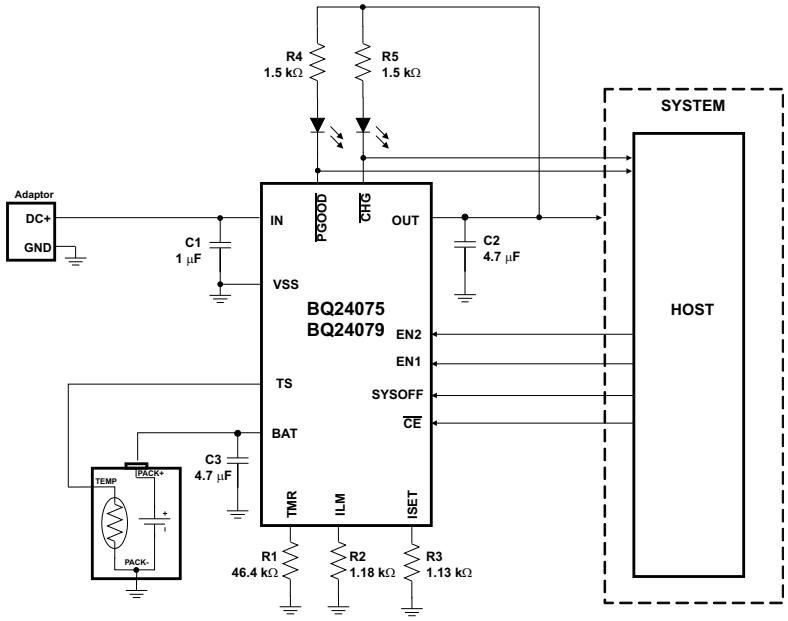


图 10-13. Using BQ24075 or BQ24079 to Disconnect the Battery From the System

11 Power Supply Recommendations

Some adapters implement a half rectifier topology, which causes the adapter output voltage to fall below the battery voltage during part of the cycle. To enable operation with adapters under those conditions, the BQ2407x family keeps the charger on for at least 20 msec (typical) after the input power puts the part in sleep mode. This feature enables use of external adapters using 50 Hz networks. The input must not drop below the UVLO voltage for the charger to work properly. Thus, the battery voltage should be above the UVLO to help prevent the input from dropping out. Additional input capacitance may be needed.

12 Layout

12.1 Layout Guidelines

- To obtain optimal performance, the decoupling capacitor from IN to GND (thermal pad) and the output filter capacitors from OUT to GND (thermal pad) should be placed as close as possible to the BQ2407x, with short trace runs to both IN, OUT and GND (thermal pad).
- All low-current GND connections should be kept separate from the high-current charge or discharge paths from the battery. Use a single-point ground technique incorporating both the small signal ground path and the power ground path.
- The high current charge paths into IN pin and from the OUT pin must be sized appropriately for the maximum charge current in order to avoid voltage drops in these traces
- The BQ2407x family is packaged in a thermally enhanced MLP package. The package includes a thermal pad to provide an effective thermal contact between the IC and the printed circuit board (PCB); this thermal pad is also the main ground connection for the device. Connect the thermal pad to the PCB ground connection. Full PCB design guidelines for this package are provided in the *QFN/SON PCB Attachment Application Note*.

12.2 Layout Example

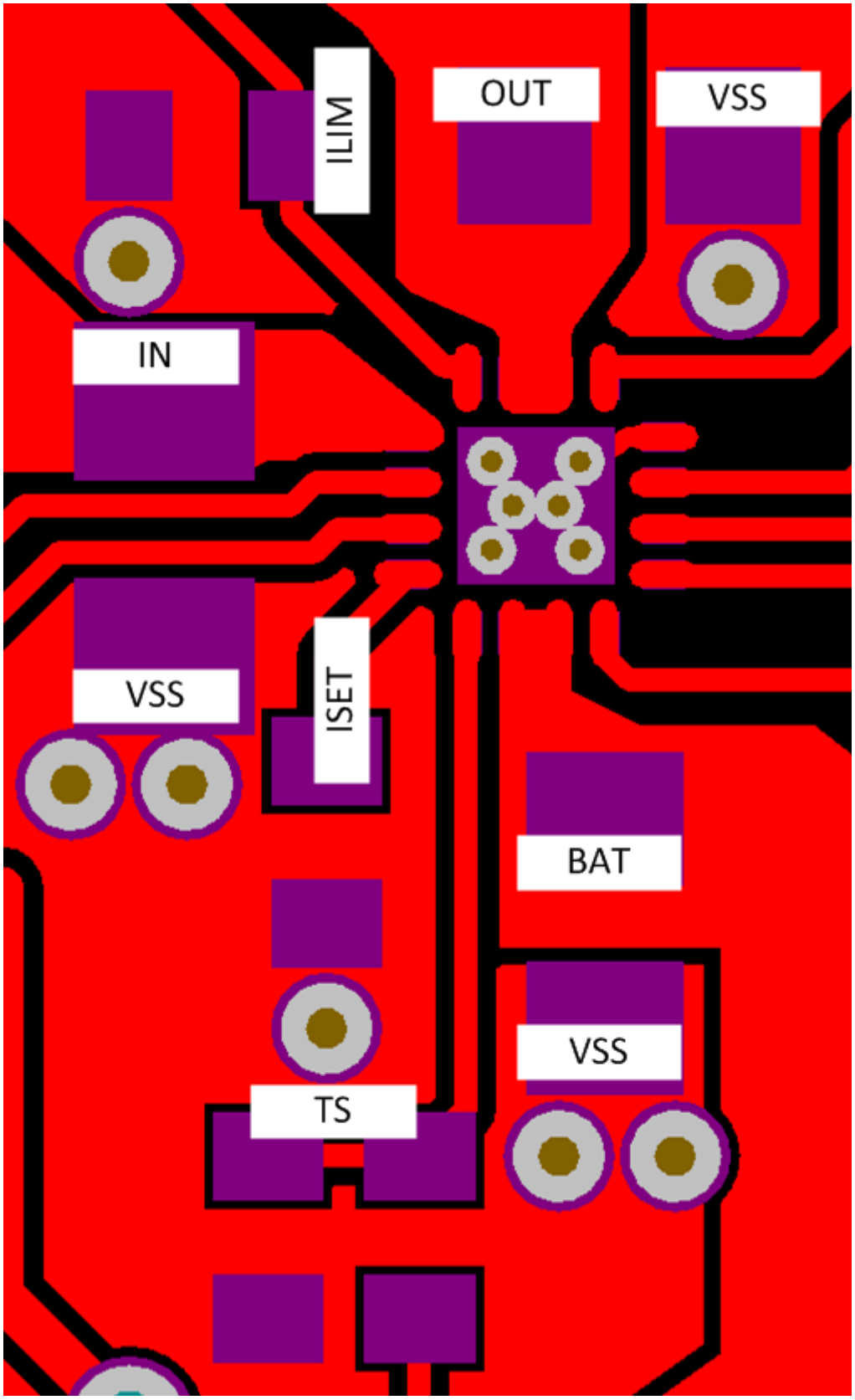


图 12-1. Layout Schematic

12.3 Thermal Considerations

The BQ24072/3/4/5 family is packaged in a thermally enhanced MLP package. The package includes a thermal pad to provide an effective thermal contact between the IC and the printed circuit board (PCB). The power pad should be directly connected to the V_{SS} pin. Full PCB design guidelines for this package are provided in the *QFN/SON PCB Attachment Application Note*. The most common measure of package thermal performance is thermal impedance (θ_{JA}) measured (or modeled) from the chip junction to the air surrounding the package surface (ambient). The mathematical expression for θ_{JA} is:

$$\theta_{JA} = (T_J - T) / P \quad (10)$$

where

- T_J = chip junction temperature
- T = ambient temperature
- P = device power dissipation

Factors that can influence the measurement and calculation of θ_{JA} include:

- Whether or not the device is board mounted
- Trace size, composition, thickness, and geometry
- Orientation of the device (horizontal or vertical)
- Volume of the ambient air surrounding the device under test and airflow
- Whether other surfaces are in close proximity to the device being tested

Due to the charge profile of Li-Ion batteries the maximum power dissipation is typically seen at the beginning of the charge cycle when the battery voltage is at its lowest. Typically after fast charge begins the pack voltage increases to ≠3.4 V within the first 2 minutes. The thermal time constant of the assembly typically takes a few minutes to heat up so when doing maximum power dissipation calculations, 3.4 V is a good minimum voltage to use. This is verified, with the system and a fully discharged battery, by plotting temperature on the bottom of the PCB under the IC (pad should have multiple vias), the charge current and the battery voltage as a function of time. The fast charge current will start to taper off if the part goes into thermal regulation.

The device power dissipation, P, is a function of the charge rate and the voltage drop across the internal PowerFET. It can be calculated from the following equation when a battery pack is being charged :

$$P = [V_{(IN)} - V_{(OUT)}] \times [I_{(OUT)} + I_{(BAT)}] + [V_{(OUT)} - V_{(BAT)}] \times I_{(BAT)} \quad (11)$$

The thermal loop feature reduces the charge current to limit excessive IC junction temperature. It is recommended that the design not run in thermal regulation for typical operating conditions (nominal input voltage and nominal ambient temperatures) and use the feature for non typical situations such as hot environments or higher than normal input source voltage. With that said, the IC will still perform as described, if the thermal loop is always active.

13 Device and Documentation Support

13.1 Device Support

13.1.1 第三方产品免责声明

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TI E2E™ 支持论坛是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《使用条款》。

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13.5 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

13.6 术语表

TI 术语表　　本术语表列出并解释了术语、首字母缩略词和定义。

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
BQ24072RGTR	ACTIVE	VQFN	RGT	16	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CKP	Samples
BQ24072RGTT	ACTIVE	VQFN	RGT	16	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CKP	Samples
BQ24073RGTR	ACTIVE	VQFN	RGT	16	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKQ	Samples
BQ24073RGTT	ACTIVE	VQFN	RGT	16	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CKQ	Samples
BQ24073RGTTG4	ACTIVE	VQFN	RGT	16	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CKQ	Samples
BQ24074RGTR	ACTIVE	VQFN	RGT	16	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	(BZF, NXK)	Samples
BQ24074RGTRG4	ACTIVE	VQFN	RGT	16	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	(BZF, NXK)	Samples
BQ24074RGTT	ACTIVE	VQFN	RGT	16	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	(BZF, NXK)	Samples
BQ24075RGTR	ACTIVE	VQFN	RGT	16	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CDU	Samples
BQ24075RGTT	ACTIVE	VQFN	RGT	16	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CDU	Samples
BQ24079RGTR	ACTIVE	VQFN	RGT	16	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ODI	Samples
BQ24079RGTT	ACTIVE	VQFN	RGT	16	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ODI	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

OTHER QUALIFIED VERSIONS OF BQ24075 :

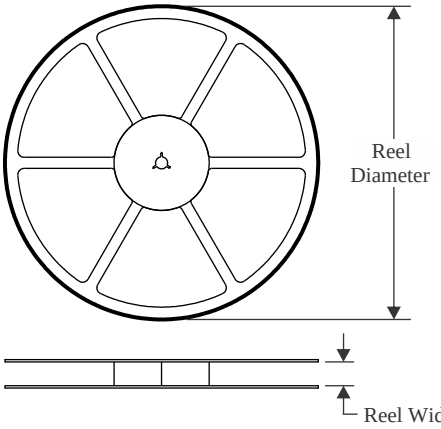
- Automotive : BQ24075-Q1

NOTE: Qualified Version Definitions:

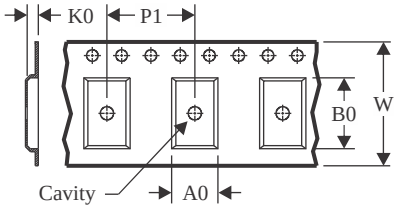
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

REEL DIMENSIONS

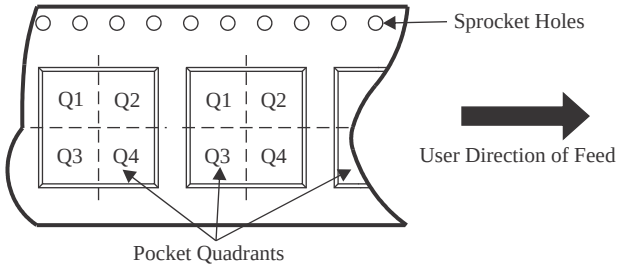


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

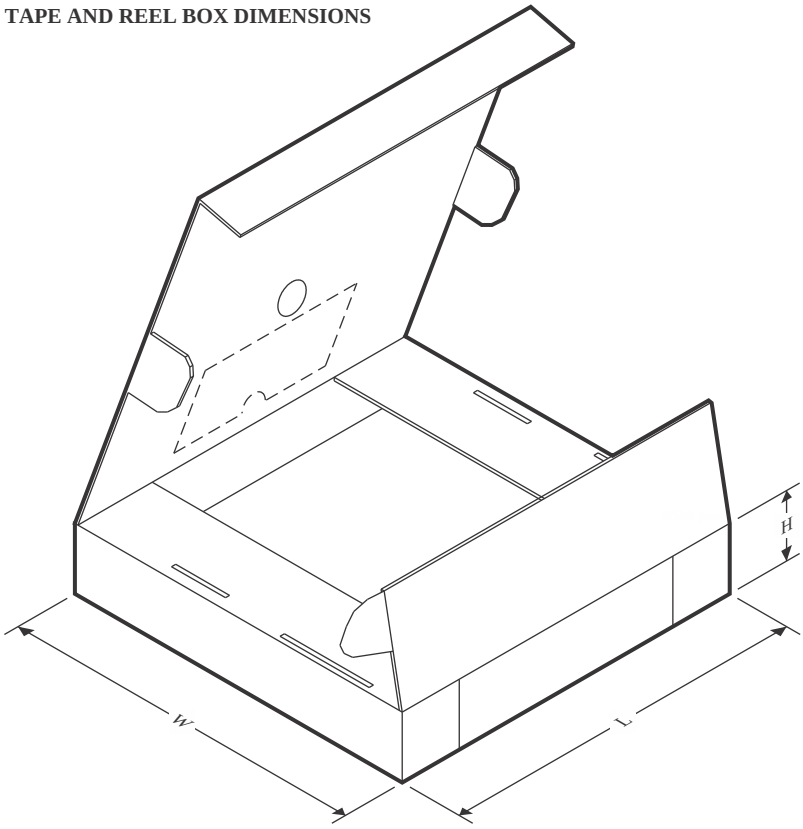
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ24072RGTR	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ24072RGTT	VQFN	RGT	16	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ24073RGTR	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ24073RGTR	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ24073RGTT	VQFN	RGT	16	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ24074RGTR	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ24074RGTT	VQFN	RGT	16	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ24075RGTR	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ24075RGTT	VQFN	RGT	16	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ24079RGTR	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
BQ24079RGTT	VQFN	RGT	16	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS

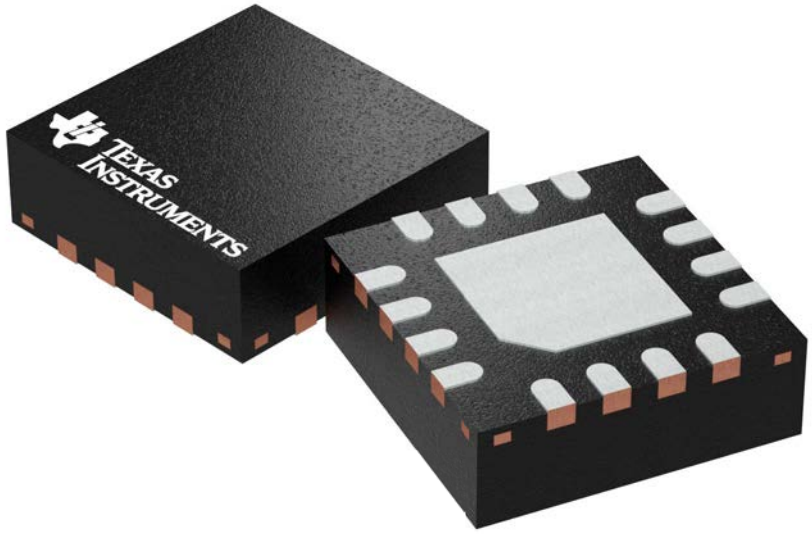


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ24072RGTR	VQFN	RGT	16	3000	346.0	346.0	33.0
BQ24072RGTT	VQFN	RGT	16	250	210.0	185.0	35.0
BQ24073RGTR	VQFN	RGT	16	3000	367.0	367.0	35.0
BQ24073RGTR	VQFN	RGT	16	3000	346.0	346.0	33.0
BQ24073RGTT	VQFN	RGT	16	250	210.0	185.0	35.0
BQ24074RGTR	VQFN	RGT	16	3000	346.0	346.0	33.0
BQ24074RGTT	VQFN	RGT	16	250	210.0	185.0	35.0
BQ24075RGTR	VQFN	RGT	16	3000	346.0	346.0	33.0
BQ24075RGTT	VQFN	RGT	16	250	210.0	185.0	35.0
BQ24079RGTR	VQFN	RGT	16	3000	346.0	346.0	33.0
BQ24079RGTT	VQFN	RGT	16	250	210.0	185.0	35.0

RGT 16 VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



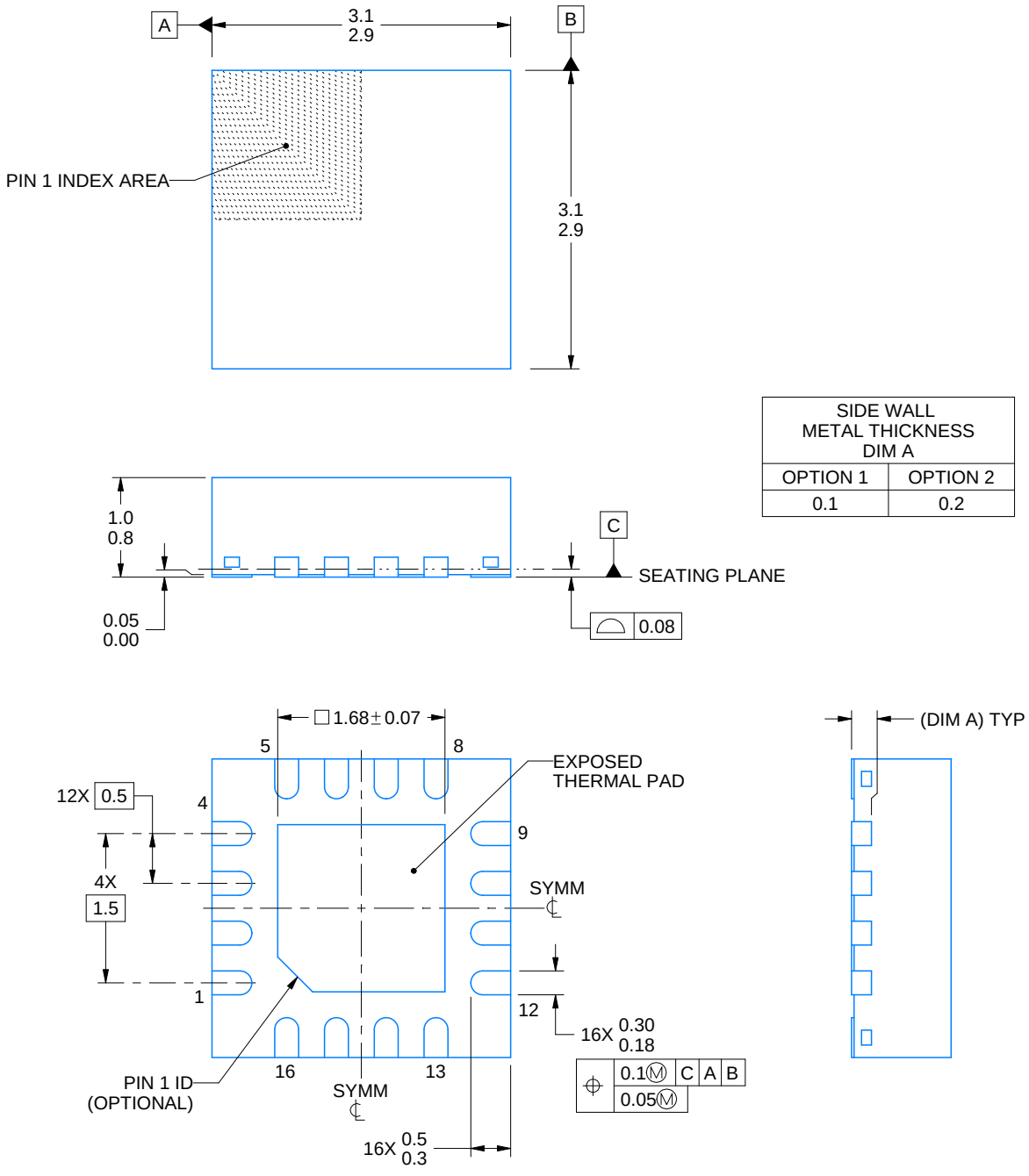
Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

PACKAGE OUTLINE

RGT0016C

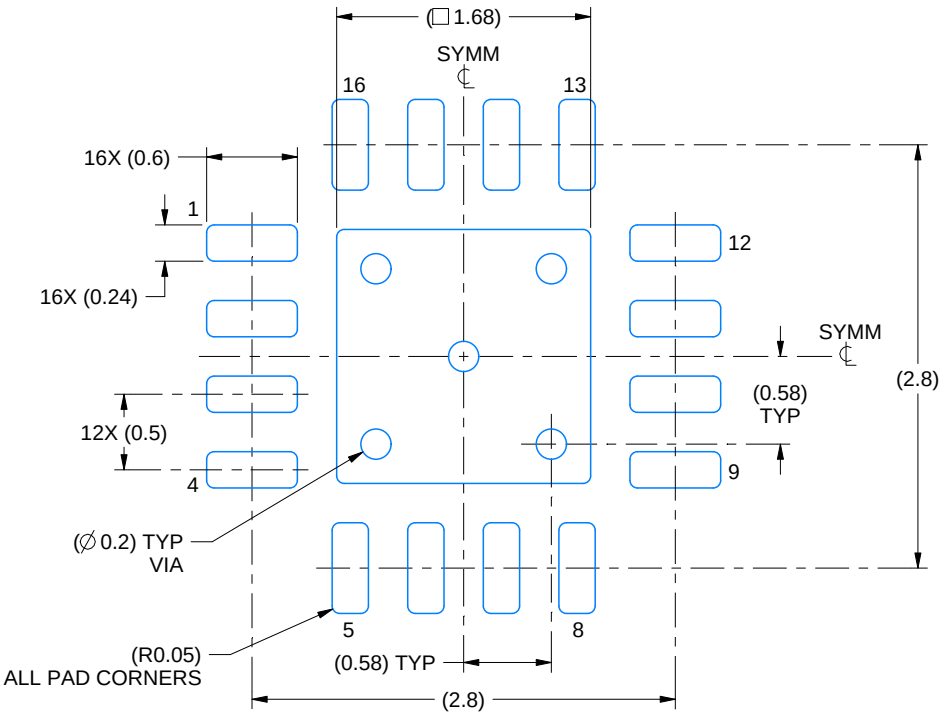
VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

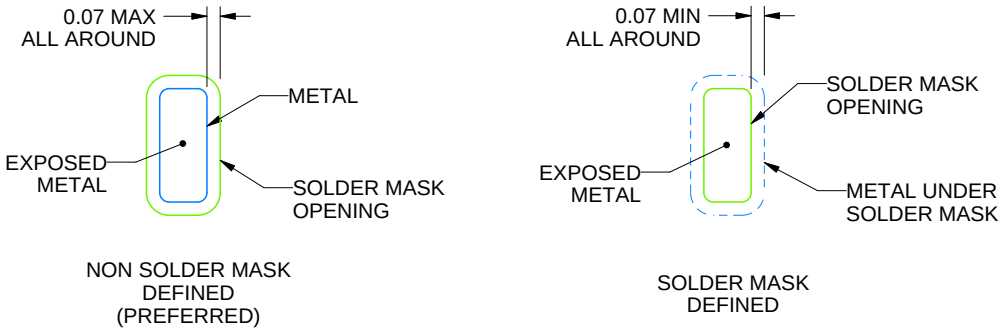


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:20X



SOLDER MASK DETAILS

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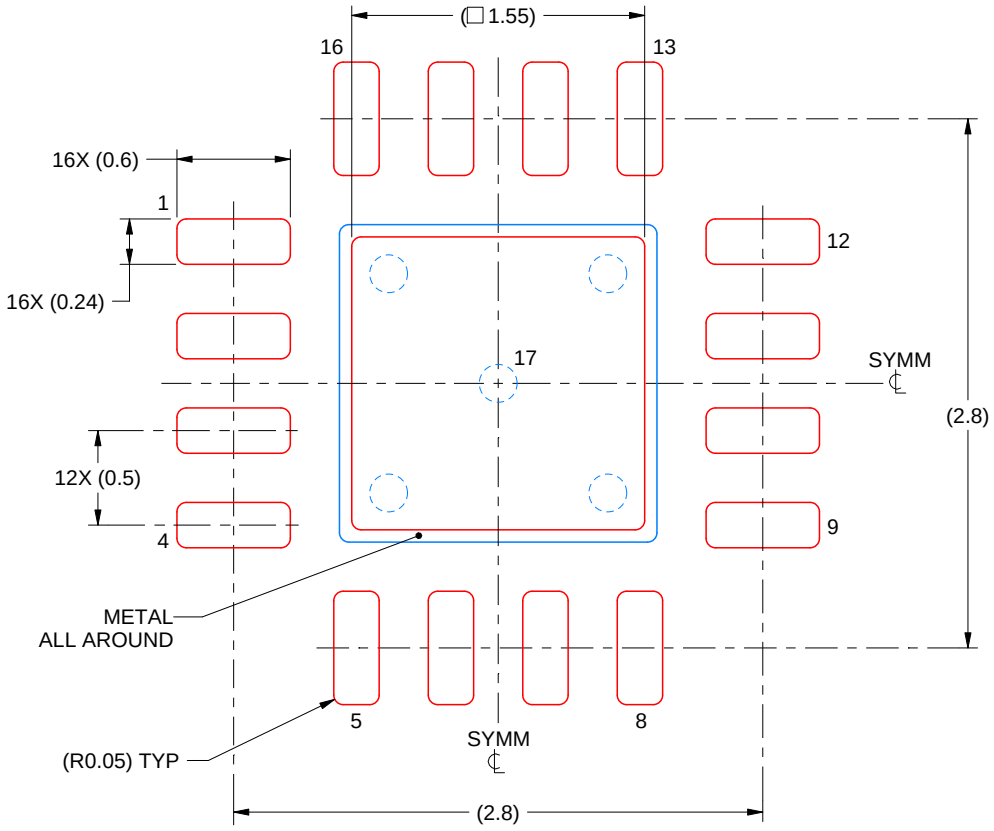
NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 17:
85% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:25X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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